

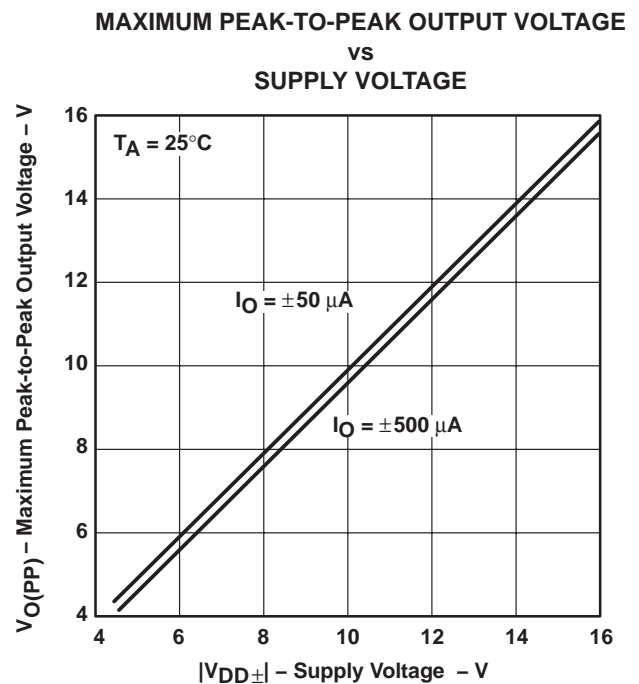
- Qualified for Automotive Applications
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 100 V Machine Model (C = 200 pF, R = 0); Exceeds 1500 V Charged Device Model
- Output Swing Includes Both Supply Rails
- Low Noise . . . 9 nV/√Hz Typ at f = 1 kHz
- Low Input Bias Current . . . 1 pA Typ
- Fully Specified for Both Single-Supply and Split-Supply Operation
- Common-Mode Input Voltage Range Includes Negative Rail
- High-Gain Bandwidth . . . 2.2 MHz Typ
- High Slew Rate . . . 3.6 V/μs Typ
- Low Input Offset Voltage  
950 μV Max at T<sub>A</sub> = 25°C
- Macromodel Included
- Performance Upgrades for the TS272, TS274, TLC272, and TLC274

## description

The TLC2272 and TLC2274 are dual and quadruple operational amplifiers from Texas Instruments. Both devices exhibit rail-to-rail output performance for increased dynamic range in single- or split-supply applications. The TLC227x family offers 2 MHz of bandwidth and 3 V/μs of slew rate for higher speed applications. These devices offer comparable ac performance while having better noise, input offset voltage, and power dissipation than existing CMOS operational amplifiers. The TLC227x has a noise voltage of 9 nV/√Hz, two times lower than competitive solutions.

The TLC227x, exhibiting high input impedance and low noise, is excellent for small-signal conditioning for high-impedance sources, such as piezoelectric transducers. Because of the micro-power dissipation levels, these devices work well in hand-held monitoring and remote-sensing applications. In addition, the rail-to-rail output feature, with single- or split-supplies, makes this family a great choice when interfacing with analog-to-digital converters (ADCs). For precision applications, the TLC227xA family is available with a maximum input offset voltage of 950 μV. This family is fully characterized at 5 V and ±5 V.

The TLC2272/4 also makes great upgrades to the TLC272/4 or TS272/4 in standard designs. They offer increased output dynamic range, lower noise voltage, and lower input offset voltage. This enhanced feature set allows them to be used in a wider range of applications. For applications that require higher output drive and wider input voltage range, see the TLV2432 and TLV2442 devices.



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**TEXAS  
INSTRUMENTS**

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# TLC227x-Q1, TLC227xA-Q1

## Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

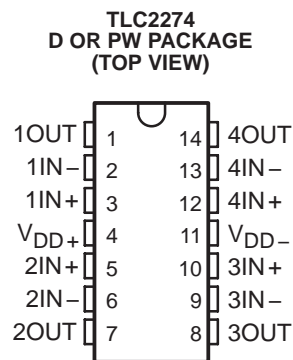
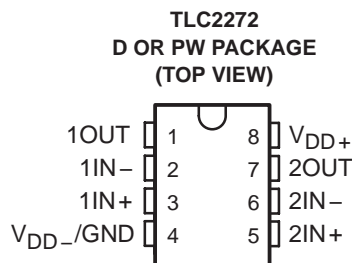
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### AVAILABLE OPTIONS†

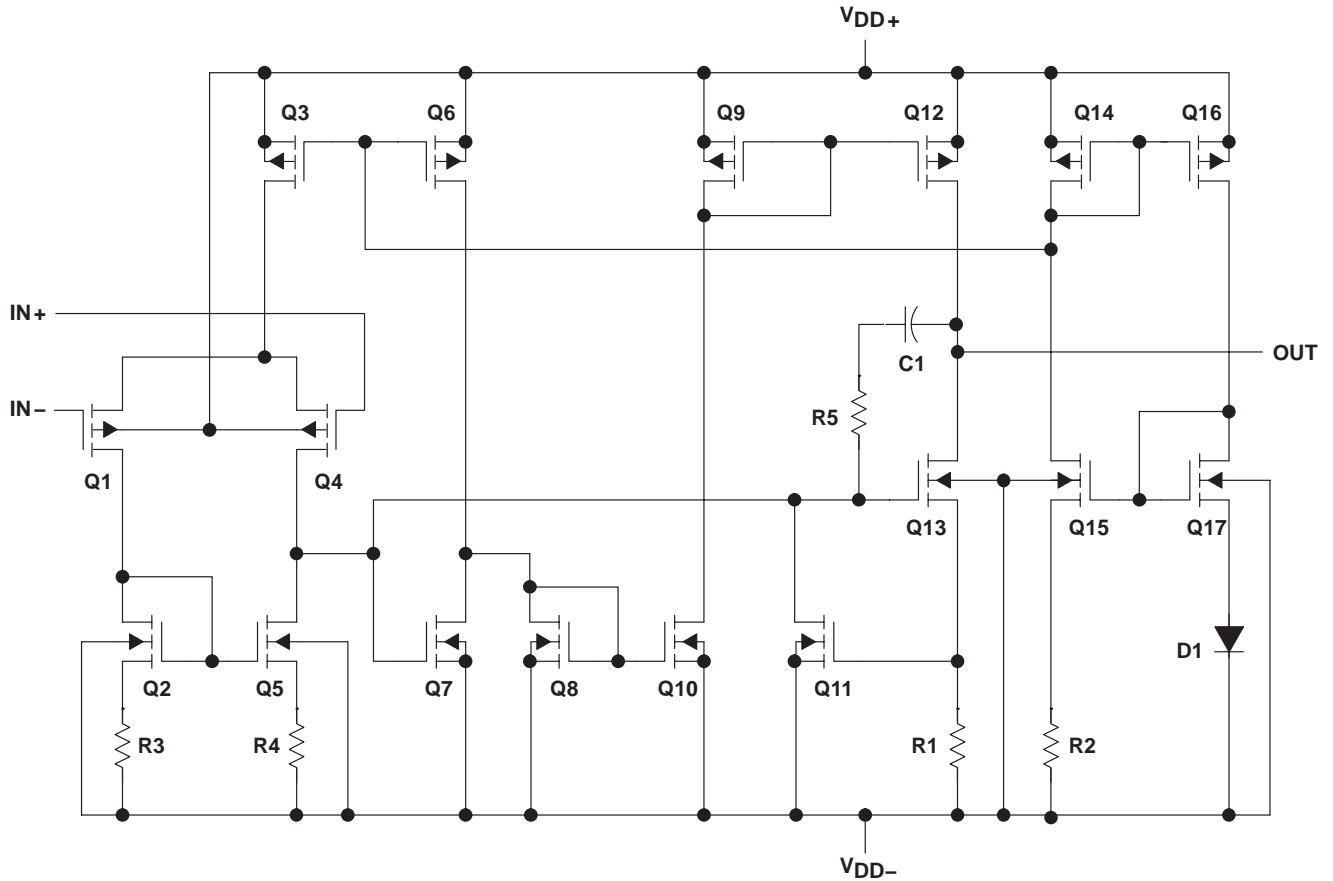
T <sub>A</sub>	V <sub>IO</sub> max At 25°C	PACKAGED DEVICES‡	
		SMALL OUTLINE (D)	TSSOP (PW)
-40°C to 125°C	950 μV 2.5 mV	TLC2272AQDRQ1 TLC2272QDRQ1	TLC2272AQPWRQ1 TLC2272QPWRQ1
-40°C to 125°C	950 μV 2.5 mV	TLC2274AQDRQ1 TLC2274QDRQ1	TLC2274AQPWRQ1 TLC2274QPWRQ1

† For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at <http://www.ti.com>.

‡ Package drawings, thermal data, and symbolization are available at <http://www.ti.com/packaging>.



equivalent schematic (each amplifier)



ACTUAL DEVICE COMPONENT COUNT†		
COMPONENT	TLC2272	TLC2274
Transistors	38	76
Resistors	26	52
Diodes	9	18
Capacitors	3	6

† Includes both amplifiers and all ESD, bias, and trim circuitry

# TLC227x-Q1, TLC227xA-Q1

## Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

SGLS007C – FEBRUARY 2003 – REVISED APRIL 2008

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, $V_{DD+}$ (see Note 1)	8 V
Supply voltage, $V_{DD-}$ (see Note 1)	-8 V
Differential input voltage, $V_{ID}$ (see Note 2)	$\pm 16$ V
Input voltage range, $V_I$ (any input, see Note 1)	$V_{DD-} - 0.3$ V to $V_{DD+}$
Input current, $I_I$ (any input)	$\pm 5$ mA
Output current, $I_O$	$\pm 50$ mA
Total current into $V_{DD+}$	$\pm 50$ mA
Total current out of $V_{DD-}$	$\pm 50$ mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range, $T_A$	-40°C to 125°C
Storage temperature range	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D or PW package	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values, except differential voltages, are with respect to the midpoint between  $V_{DD+}$  and  $V_{DD-}$ .
  2. Differential voltages are at  $IN+$  with respect to  $IN-$ . Excessive current will flow if input is brought below  $V_{DD-} - 0.3$  V.
  3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D-8	725 mW	5.8 mW/°C	464 mW	337 mW	145 mW
D-14	950 mW	7.6 mW/°C	608 mW	494 mW	190 mW
PW-8	525 mW	4.2 mW/°C	336 mW	273 mW	105 mW
PW-14	700 mW	5.6 mW/°C	448 mW	364 mW	—

### recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, $V_{DD\pm}$	$\pm 2.2$	$\pm 8$	V
Input voltage, $V_I$	$V_{DD-}$	$V_{DD+} - 1.5$	V
Common-mode input voltage, $V_{IC}$	$V_{DD-}$	$V_{DD+} - 1.5$	V
Operating free-air temperature, $T_A$	-40	125	°C



**TLC227x-Q1, TLC227xA-Q1**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SGLS007C – FEBRUARY 2003 – REVISED APRIL 2008

**TLC2272Q electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2272Q			TLC2272AQ			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0\text{ V},$ $V_O = 0\text{ V},$ $V_{DD\pm} = \pm 2.5\text{ V},$ $R_S = 50\ \Omega$	25°C	300	2500		300	950	$\mu\text{V}$	
		Full range			3000		1500		
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 125°C	2			2		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.002			0.002		$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	pA	
		Full range			800		800		
$I_{IB}$ Input bias current	25°C	1	60		1	60	pA		
	Full range			800		800			
$V_{ICR}$ Common-mode input voltage	$R_S = 50\ \Omega,$ $ V_{IO}  \leq 5\text{ mV}$	25°C	0 to 4	-0.3 to 4.2		0 to 4	-0.3 to 4.2	V	
		Full range	0 to 3.5			0 to 3.5			
$V_{OH}$ High-level output voltage	$I_{OH} = -20\ \mu\text{A}$ $I_{OH} = -200\ \mu\text{A}$ $I_{OH} = -1\text{ mA}$	25°C	4.99			4.99	V		
		25°C	4.85	4.93		4.85		4.93	
		Full range	4.85			4.85			
		25°C	4.25	4.65		4.25		4.65	
$V_{OL}$ Low-level output voltage	$V_{IC} = 2.5\text{ V},$ $I_{OL} = 50\ \mu\text{A}$ $V_{IC} = 2.5\text{ V},$ $I_{OL} = 500\ \mu\text{A}$ $V_{IC} = 2.5\text{ V},$ $I_{OL} = 5\text{ mA}$	25°C	0.01			0.01	V		
		25°C	0.09	0.15		0.09		0.15	
		Full range			0.15			0.15	
		25°C	0.9	1.5		0.9		1.5	
$A_{VD}$ Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V},$ $V_O = 1\text{ V to }4\text{ V}$	$R_L = 10\text{ k}\Omega$ ‡	25°C	10	35		10	35	V/mV
			Full range	10			10		
		$R_L = 1\text{ m}\Omega$ ‡	25°C	175			175		
$r_{id}$ Differential input resistance		25°C	$10^{12}$			$10^{12}$	$\Omega$		
$r_i$ Common-mode input resistance		25°C	$10^{12}$			$10^{12}$	$\Omega$		
$c_i$ Common-mode input capacitance	$f = 10\text{ kHz},$ P package	25°C	8			8	pF		
$z_o$ Closed-loop output impedance	$f = 1\text{ MHz},$ $A_V = 10$	25°C	140			140	$\Omega$		
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ V to }2.7\text{ V},$ $V_O = 2.5\text{ V},$ $R_S = 50\ \Omega$	25°C	70	75		70	75	dB	
		Full range	70			70			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 4.4\text{ V to }16\text{ V},$ $V_{IC} = V_{DD}/2,$ No load	25°C	80	95		80	95	dB	
		Full range	80			80			
$I_{DD}$ Supply current	$V_O = 2.5\text{ V},$ No load	25°C	2.2	3		2.2	3	mA	
		Full range			3		3		

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



**TLC227x-Q1, TLC227xA-Q1**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SGLS007C – FEBRUARY 2003 – REVISED APRIL 2008

**TLC2272Q operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2272Q			TLC2272AQ			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain $V_O = 1.25\text{ V to }2.75\text{ V}$ , $R_L = 10\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C	2.3	3.6		2.3	3.6	V/ $\mu\text{s}$	
		Full range	1.7			1.7			
$V_n$	Equivalent input noise voltage $f = 10\text{ Hz}$ $f = 1\text{ kHz}$	25°C		50			50	nV/ $\sqrt{\text{Hz}}$	
		25°C		9			9		
$V_{NPP}$	Peak-to-peak equivalent input noise voltage $f = 0.1\text{ Hz to }1\text{ Hz}$ $f = 0.1\text{ Hz to }10\text{ Hz}$	25°C		1			1	$\mu\text{V}$	
		25°C		1.4			1.4		
$I_n$	Equivalent input noise current	25°C		0.6			0.6	fA/ $\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise $V_O = 0.5\text{ V to }2.5\text{ V}$ , $f = 20\text{ kHz}$ , $R_L = 10\text{ k}\Omega$ ‡	25°C		$A_V = 1$		0.0013%		0.0013%	
				$A_V = 10$		0.004%		0.004%	
				$A_V = 100$		0.03%		0.03%	
	Gain-bandwidth product $f = 10\text{ kHz}$ , $R_L = 10\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C		2.18			2.18	MHz	
BOM	Maximum output-swing bandwidth $V_{O(PP)} = 2\text{ V}$ , $R_L = 10\text{ k}\Omega$ ‡, $A_V = 1$ , $C_L = 100\text{ pF}$ ‡	25°C		1			1	MHz	
$t_s$	Settling time $A_V = -1$ , Step = 0.5 V to 2.5 V, $R_L = 10\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C		To 0.1%		1.5		1.5	
				To 0.01%		2.6		2.6	
$\phi_m$	Phase margin at unity gain $R_L = 10\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡	25°C		50°			50°		
	Gain margin	25°C		10			10	dB	

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part.

‡ Referenced to 2.5 V



**TLC227x-Q1, TLC227xA-Q1**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SGLS007C – FEBRUARY 2003 – REVISED APRIL 2008

**TLC2272Q electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2272Q			TLC2272AQ			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0\text{ V},$ $R_S = 50\ \Omega$ $V_O = 0\text{ V},$	25°C	300	2500		300	950	$\mu\text{V}$	
		Full range			3000		1500		
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 125°C	2			2		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.002			0.002		$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	$\text{pA}$	
		Full range			800		800		
$I_{IB}$ Input bias current		25°C	1	60		1	60	$\text{pA}$	
		Full range			800		800		
$V_{ICR}$ Common-mode input voltage	$R_S = 50\ \Omega,$ $ V_{IO}  \leq 5\text{ mV}$	25°C	-5 to 4	-5.3 to 4.2		-5 to 4	-5.3 to 4.2	$\text{V}$	
		Full range	-5 to 3.5			-5 to 3.5			
$V_{OM+}$ Maximum positive peak output voltage	$I_O = -20\ \mu\text{A}$ $I_O = -200\ \mu\text{A}$ $I_O = -1\text{ mA}$	25°C		4.99			4.99	$\text{V}$	
		25°C	4.85	4.93		4.85	4.93		
		Full range	4.85			4.85			
		25°C	4.25	4.65		4.25	4.65		
$V_{OM-}$ Maximum negative peak output voltage	$V_{IC} = 0\text{ V},$ $I_O = 50\ \mu\text{A}$ $V_{IC} = 0\text{ V},$ $I_O = 500\ \mu\text{A}$ $V_{IC} = 0\text{ V},$ $I_O = 5\text{ mA}$	25°C		-4.99			-4.99	$\text{V}$	
		25°C	-4.85	-4.91		-4.85	-4.91		
		Full range	-4.85			-4.85			
		25°C	-3.5	-4.1		-3.5	-4.1		
$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 4\text{ V}$	$R_L = 10\ \text{k}\Omega$	25°C	20	50		20	50	$\text{V}/\text{mV}$
			Full range	20			20		
		$R_L = 1\ \text{m}\Omega$	25°C		300			300	
$r_{id}$ Differential input resistance		25°C		$10^{12}$			$10^{12}$	$\Omega$	
$r_i$ Common-mode input resistance		25°C		$10^{12}$			$10^{12}$	$\Omega$	
$c_i$ Common-mode input capacitance	$f = 10\ \text{kHz},$ P package	25°C		8			8	$\text{pF}$	
$z_o$ Closed-loop output impedance	$f = 1\ \text{MHz},$ $A_V = 10$	25°C		130			130	$\Omega$	
CMRR Common-mode rejection ratio	$V_{IC} = -5\text{ V to } 2.7\text{ V},$ $V_O = 0\text{ V},$ $R_S = 50\ \Omega$	25°C	75	80		75	80	$\text{dB}$	
		Full range	75			75			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD} = \pm 2.2\text{ V to } \pm 8\text{ V},$ $V_{IC} = 0\text{ V},$ No load	25°C	80	95		80	95	$\text{dB}$	
		Full range	80			80			
$I_{DD}$ Supply current	$V_O = 2.5\text{ V},$ No load	25°C	2.4	3		2.4	3	$\text{mA}$	
		Full range			3		3		

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



**TLC227x-Q1, TLC227xA-Q1**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SGLS007C – FEBRUARY 2003 – REVISED APRIL 2008

**TLC2272Q operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2272Q			TLC2272AQ			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain $V_O = \pm 1\text{ V}$ , $C_L = 100\text{ pF}$ $R_L = 10\text{ k}\Omega$	25°C	2.3	3.6		2.3	3.6	V/ $\mu$ s	
		Full range	1.7			1.7			
$V_n$	Equivalent input noise voltage	25°C		50			50	nV/ $\sqrt{\text{Hz}}$	
		25°C		9			9		
$V_{NPP}$	Peak-to-peak equivalent input noise voltage	25°C		1			1	$\mu$ V	
		25°C		1.4			1.4		
$I_n$	Equivalent input noise current	25°C		0.6			0.6	fA/ $\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise $V_O = \pm 2.3\text{ V}$ $R_L = 10\text{ k}\Omega$ , $f = 20\text{ kHz}$	25°C		$A_V = 1$	0.0011%		0.0011%		
				$A_V = 10$	0.004%		0.004%		
				$A_V = 100$	0.03%		0.03%		
	Gain-bandwidth product	25°C		2.25			2.25	MHz	
BOM	Maximum output-swing bandwidth $V_{O(PP)} = 4.6\text{ V}$ , $R_L = 10\text{ k}\Omega$	25°C		0.54			0.54	MHz	
$t_s$	Settling time $A_V = -1$ , Step = $-2.3\text{ V}$ to $2.3\text{ V}$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		To 0.1%	1.5		1.5	$\mu$ s	
				To 0.01%	3.2		3.2		
$\phi_m$	Phase margin at unity gain	25°C		52°			52°		
	Gain margin	25°C		10			10	dB	

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part.



**TLC227x-Q1, TLC227xA-Q1**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SGLS007C – FEBRUARY 2003 – REVISED APRIL 2008

**TLC2274Q electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2274Q			TLC2274AQ			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{DD} \pm \pm 2.5\text{ V}$ , $V_O = 0\text{ V}$ , $V_{IC} = 0\text{ V}$ , $R_S = 50\ \Omega$	25°C	300	2500		300	950	$\mu\text{V}$	
		Full range		3000		1500			
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 125°C	2			2		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.002			0.002		$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	$\text{pA}$	
		Full range		800		800			
$I_{IB}$ Input bias current	25°C	1	60		1	60	$\text{pA}$		
	Full range		800		800				
$V_{ICR}$ Common-mode input voltage	$R_S = 50\ \Omega$ , $ V_{IO}  \leq 5\text{ mV}$	25°C	0 to 4	-0.3 to 4.2		0 to 4	-0.3 to 4.2	$\text{V}$	
		Full range	0 to 3.5			0 to 3.5			
$V_{OH}$ High-level output voltage	$I_{OH} = -20\ \mu\text{A}$	25°C	4.99			4.99	$\text{V}$		
		25°C	4.85	4.93		4.85		4.93	
		Full range	4.85			4.85			
		25°C	4.25	4.65		4.25		4.65	
$V_{OL}$ Low-level output voltage	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 50\ \mu\text{A}$	25°C	0.01			0.01	$\text{V}$		
		25°C	0.09	0.15		0.09		0.15	
		Full range		0.15				0.15	
		25°C	0.9	1.5		0.9		1.5	
$V_{OL}$ Low-level output voltage	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 500\ \mu\text{A}$	25°C					$\text{V}$		
		25°C							
		Full range							
		25°C							
$V_{OL}$ Low-level output voltage	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 5\text{ mA}$	25°C					$\text{V}$		
		25°C							
		Full range							
		25°C							
$A_{VD}$ Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}$ , $V_O = 1\text{ V to }4\text{ V}$	$R_L = 10\text{ k}\Omega$ ‡	25°C	10	35		10	35	$\text{V/mV}$
			Full range	10			10		
		$R_L = 1\text{ M}\Omega$ ‡	25°C	175			175		
$r_{id}$ Differential input resistance		25°C	$10^{12}$			$10^{12}$	$\Omega$		
$r_i$ Common-mode input resistance		25°C	$10^{12}$			$10^{12}$	$\Omega$		
$c_i$ Common-mode input capacitance	$f = 10\text{ kHz}$ , N package	25°C	8			8	$\text{pF}$		
$z_o$ Closed-loop output impedance	$f = 1\text{ MHz}$ , $A_V = 10$	25°C	140			140	$\Omega$		
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ V to }2.7\text{ V}$ , $V_O = 2.5\text{ V}$ , $R_S = 50\ \Omega$	25°C	70	75		70	75	dB	
		Full range	70			70			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 4.4\text{ V to }16\text{ V}$ , $V_{IC} = V_{DD}/2$ , No load	25°C	80	95		80	95	dB	
		Full range	80			80			
$I_{DD}$ Supply current	$V_O = 2.5\text{ V}$ , No load	25°C	4.4	6		4.4	6	mA	
		Full range		6			6		

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



**TLC227x-Q1, TLC227xA-Q1**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SGLS007C – FEBRUARY 2003 – REVISED APRIL 2008

**TLC2274Q operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2274Q			TLC2274AQ			UNIT		
			MIN	TYP	MAX	MIN	TYP	MAX			
SR	Slew rate at unity gain $V_O = 0.5\text{ V to }2.5\text{ V},$ $R_L = 10\text{ k}\Omega^\ddagger,$ $C_L = 100\text{ pF}^\ddagger$	25°C	2.3	3.6		2.3	3.6	V/ $\mu\text{s}$			
		Full range	1.7			1.7					
$V_n$	Equivalent input noise voltage	$f = 10\text{ Hz}$	25°C	50			50			nV/ $\sqrt{\text{Hz}}$	
		$f = 1\text{ kHz}$	25°C	9			9				
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$	25°C	1			1			$\mu\text{V}$	
		$f = 0.1\text{ Hz to }10\text{ Hz}$	25°C	1.4			1.4				
$I_n$	Equivalent input noise current		25°C	0.6			0.6			fA/ $\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise $V_O = 0.5\text{ V to }2.5\text{ V},$ $f = 20\text{ kHz},$ $R_L = 10\text{ k}\Omega^\ddagger$	$A_V = 1$	25°C	0.0013%			0.0013%				
		$A_V = 10$		0.004%			0.004%				
		$A_V = 100$		0.03%			0.03%				
	Gain-bandwidth product	$f = 10\text{ kHz},$ $C_L = 100\text{ pF}^\ddagger$	25°C	2.18			2.18			MHz	
BOM	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V},$ $R_L = 10\text{ k}\Omega^\ddagger,$ $A_V = 1,$ $C_L = 100\text{ pF}^\ddagger$	25°C	1			1			MHz	
$t_s$	Settling time	$A_V = -1,$ Step = 0.5 V to 2.5 V, $R_L = 10\text{ k}\Omega^\ddagger,$ $C_L = 100\text{ pF}^\ddagger$	To 0.1%	25°C	1.5			1.5			$\mu\text{s}$
			To 0.01%		2.6			2.6			
$\phi_m$	Phase margin at unity gain	$R_L = 10\text{ k}\Omega^\ddagger,$ $C_L = 100\text{ pF}^\ddagger$	25°C	50°			50°				
	Gain margin		25°C	10			10			dB	

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part.

‡ Referenced to 2.5 V



**TLC227x-Q1, TLC227xA-Q1**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SGLS007C – FEBRUARY 2003 – REVISED APRIL 2008

**TLC2274Q electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2274Q			TLC2274AQ			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
$V_{IO}$ Input offset voltage	$V_{IC} = 0\text{ V}, V_O = 0\text{ V}, R_S = 50\ \Omega$	25°C	300	2500		300	950	$\mu\text{V}$		
		Full range			3000		1500			
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 125°C	2			2			$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.002			0.002			$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	$\text{pA}$		
		Full range			800		800			
$I_{IB}$ Input bias current		25°C	1	60		1	60	$\text{pA}$		
		Full range			800		800			
$V_{ICR}$ Common-mode input voltage	$R_S = 50\ \Omega,  V_{IO}  \leq 5\text{ mV}$	25°C	-5 to 4	-5.3 to 4.2		-5 to 4	-5.3 to 4.2	V		
		Full range	-5 to 3.5			-5 to 3.5				
$V_{OM+}$ Maximum positive peak output voltage	$I_O = -20\ \mu\text{A}$	25°C	4.99		4.99		V			
		25°C	4.85	4.93	4.85	4.93				
		Full range	4.85		4.85					
		25°C	4.25	4.65	4.25	4.65				
$V_{OM-}$ Maximum negative peak output voltage	$I_O = -1\text{ mA}$	25°C	-4.99		-4.99		V			
		25°C	-4.85	-4.91	-4.85	-4.91				
		Full range	-4.85		-4.85					
		25°C	-3.5	-4.1	-3.5	-4.1				
$V_{AVD}$ Large-signal differential voltage amplification	$V_O = \pm 4\text{ V}$	$R_L = 10\text{ k}\Omega$	25°C	20	50	20	50	V/mV		
			Full range	20		20				
		$R_L = 1\text{ M}\Omega$	25°C	300			300			
			Full range	300			300			
$r_{id}$ Differential input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$	
$r_i$ Common-mode input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$	
$c_i$ Common-mode input capacitance	$f = 10\text{ kHz}, \text{ N package}$	25°C	8			8			pF	
$z_o$ Closed-loop output impedance	$f = 1\text{ MHz}, A_V = 10$	25°C	130			130			$\Omega$	
CMRR Common-mode rejection ratio	$V_{IC} = -5\text{ V to } 2.7\text{ V}$ $V_O = 0\text{ V}, R_S = 50\ \Omega$	25°C	75	80		75	80	dB		
		Full range	75			75				
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD\pm} = \pm 2.2\text{ V to } \pm 8\text{ V}, V_{IC} = 0\text{ V}, \text{ No load}$	25°C	80	95		80	95	dB		
		Full range	80			80				
$I_{DD}$ Supply current	$V_O = 0\text{ V}, \text{ No load}$	25°C	4.8	6		4.8	6	mA		
		Full range	6			6				

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



**TLC227x-Q1, TLC227xA-Q1**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SGLS007C – FEBRUARY 2003 – REVISED APRIL 2008

**TLC2274Q operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2274Q			TLC2274AQ			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain $V_O = \pm 2.3\text{ V}$ , $C_L = 100\text{ pF}$ , $R_L = 10\text{ k}\Omega$	25°C	2.3	3.6		2.3	3.6	V/ $\mu$ s	
		Full range	1.7			1.7			
$V_n$	Equivalent input noise voltage $f = 10\text{ Hz}$ $f = 1\text{ kHz}$	25°C		50			50	nV/ $\sqrt{\text{Hz}}$	
		25°C		9			9		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage $f = 0.1\text{ Hz to }1\text{ Hz}$ $f = 0.1\text{ Hz to }10\text{ Hz}$	25°C		1			1	$\mu$ V	
		25°C		1.4			1.4		
$I_n$	Equivalent input noise current	25°C		0.6			0.6	fA/ $\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise $V_O = \pm 2.3\text{ V}$ , $R_L = 10\text{ k}\Omega$ , $f = 20\text{ kHz}$	25°C		$A_V = 1$		0.0011%		0.0011%	
				$A_V = 10$		0.004%		0.004%	
				$A_V = 100$		0.03%		0.03%	
	Gain-bandwidth product $f = 10\text{ kHz}$ , $C_L = 100\text{ pF}$ , $R_L = 10\text{ k}\Omega$	25°C		2.25			2.25	MHz	
BOM	Maximum output-swing bandwidth $V_{O(PP)} = 4.6\text{ V}$ , $R_L = 10\text{ k}\Omega$ , $A_V = 1$ , $C_L = 100\text{ pF}$	25°C		0.54			0.54	MHz	
$t_s$	Settling time $A_V = -1$ , Step = $-2.3\text{ V to }2.3\text{ V}$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		To 0.1%		1.5		1.5	
				To 0.01%		3.2		3.2	
$\phi_m$	Phase margin at unit gain $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		52°			52°		
		25°C		10			10	dB	

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part.

## TYPICAL CHARACTERISTICS

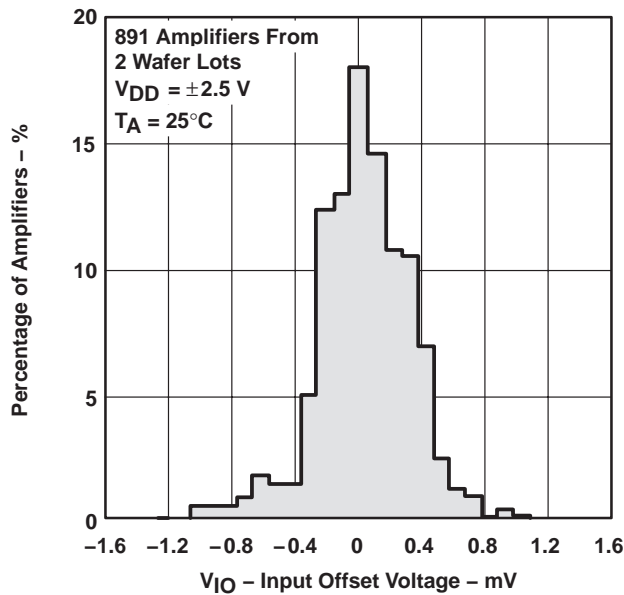
**Table of Graphs**

		FIGURE
$V_{IO}$	Input offset voltage	Distribution vs Common-mode voltage 1 – 4 5, 6
$\alpha_{VIO}$	Input offset voltage temperature coefficient	Distribution 7 – 10
$I_{IB}/I_{IO}$	Input bias and input offset current	vs Free-air temperature 11
$V_I$	Input voltage	vs Supply voltage vs Free-air temperature 12 13
$V_{OH}$	High-level output voltage	vs High-level output current 14
$V_{OL}$	Low-level output voltage	vs Low-level output current 15, 16
$V_{OM+}$	Maximum positive peak output voltage	vs Output current 17
$V_{OM-}$	Maximum negative peak output voltage	vs Output current 18
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency 19
$I_{OS}$	Short-circuit output current	vs Supply voltage vs Free-air temperature 20 21
$V_O$	Output voltage	vs Differential input voltage 22, 23
$A_{VD}$	Large-signal differential voltage amplification	vs Load resistance 24
	Large-signal differential voltage amplification and phase margin	vs Frequency 25, 26
	Large-signal differential voltage amplification	vs Free-air temperature 27, 28
$z_o$	Output impedance	vs Frequency 29, 30
CMRR	Common-mode rejection ratio	vs Frequency 31
		vs Free-air temperature 32
$k_{SVR}$	Supply-voltage rejection ratio	vs Frequency 33, 34
		vs Free-air temperature 35
$I_{DD}$	Supply current	vs Supply voltage 36, 37
		vs Free-air temperature 38, 39
SR	Slew rate	vs Load capacitance 40
		vs Free-air temperature 41
$V_O$	Inverting large-signal pulse response	42, 43
	Voltage-follower large-signal pulse response	44, 45
	Inverting small-signal pulse response	46, 47
	Voltage-follower small-signal pulse response	48, 49
$V_n$	Equivalent input noise voltage	vs Frequency 50, 51
	Noise voltage over a 10-second period	52
	Integrated noise voltage	vs Frequency 53
THD + N	Total harmonic distortion plus noise	vs Frequency 54
	Gain-bandwidth product	vs Supply voltage 55
		vs Free-air temperature 56
$\phi_m$	Phase margin	vs Load capacitance 57
	Gain margin	vs Load capacitance 58

NOTE: For all graphs where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V.

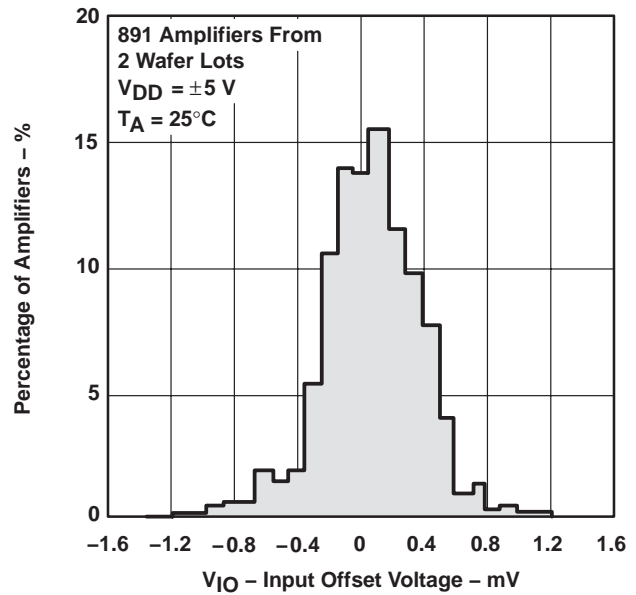
**TYPICAL CHARACTERISTICS**

**DISTRIBUTION OF TLC2272  
INPUT OFFSET VOLTAGE**



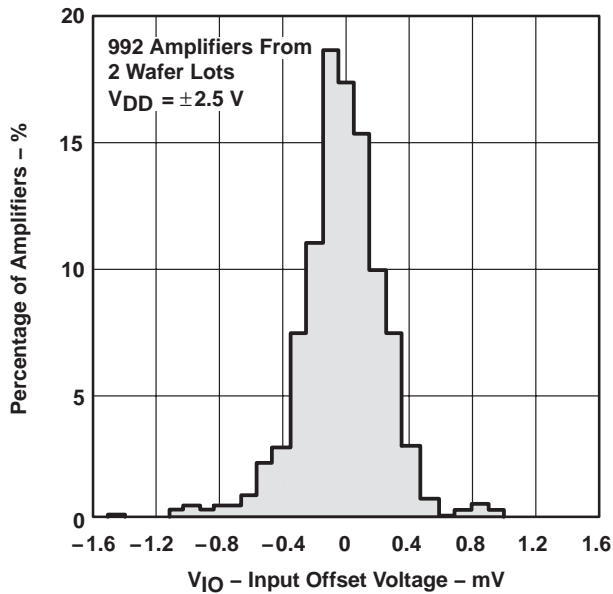
**Figure 1**

**DISTRIBUTION OF TLC2272  
INPUT OFFSET VOLTAGE**



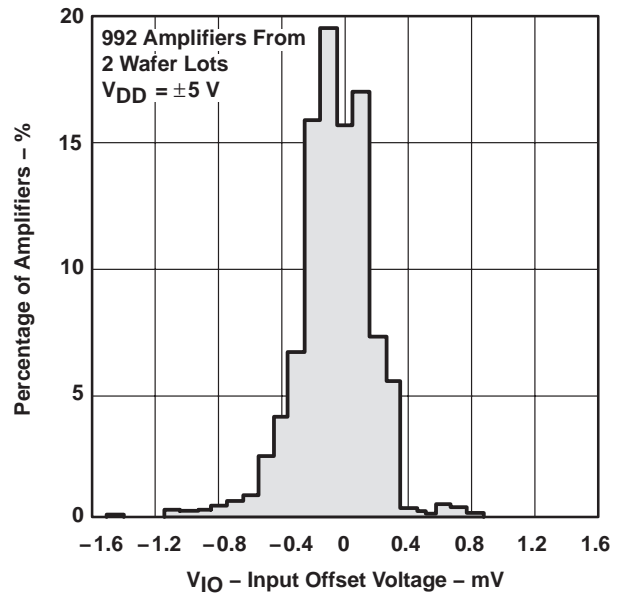
**Figure 2**

**DISTRIBUTION OF TLC2274  
INPUT OFFSET VOLTAGE**



**Figure 3**

**DISTRIBUTION OF TLC2274  
INPUT OFFSET VOLTAGE**



**Figure 4**

TYPICAL CHARACTERISTICS

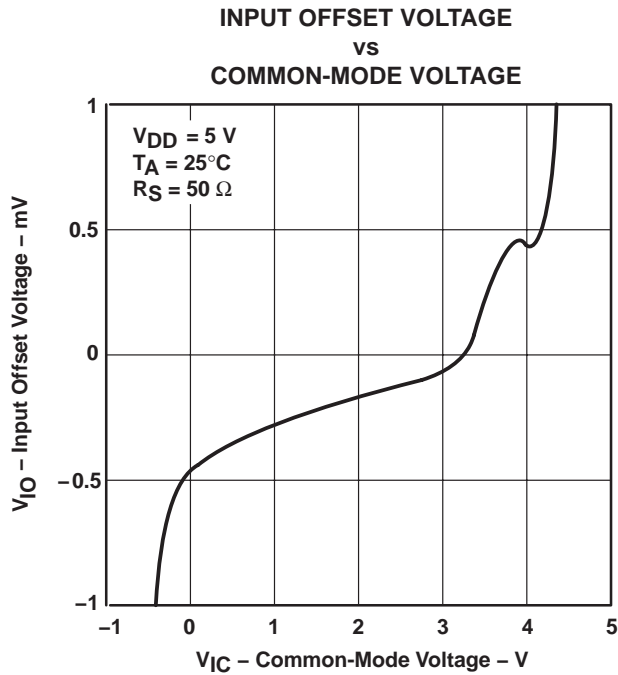


Figure 5

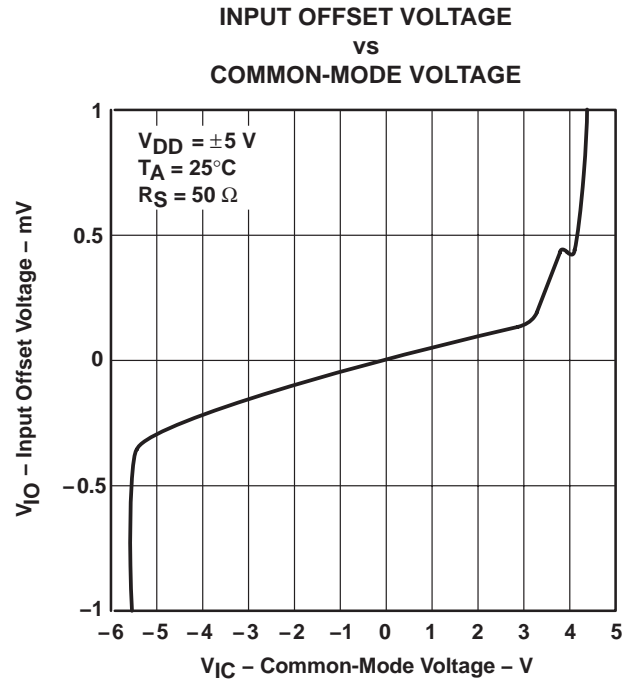


Figure 6

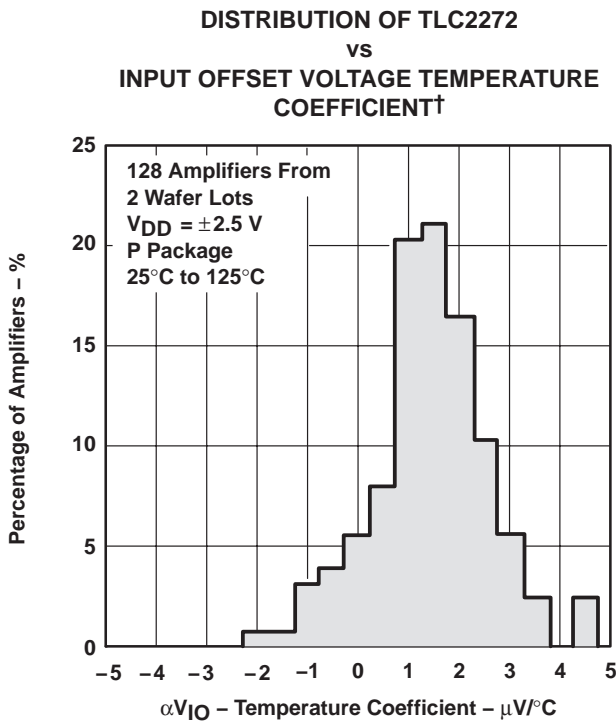


Figure 7

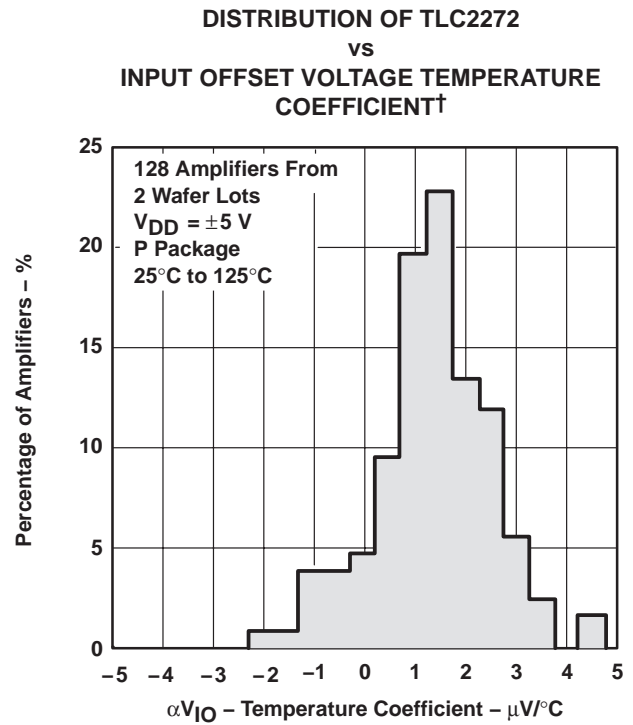
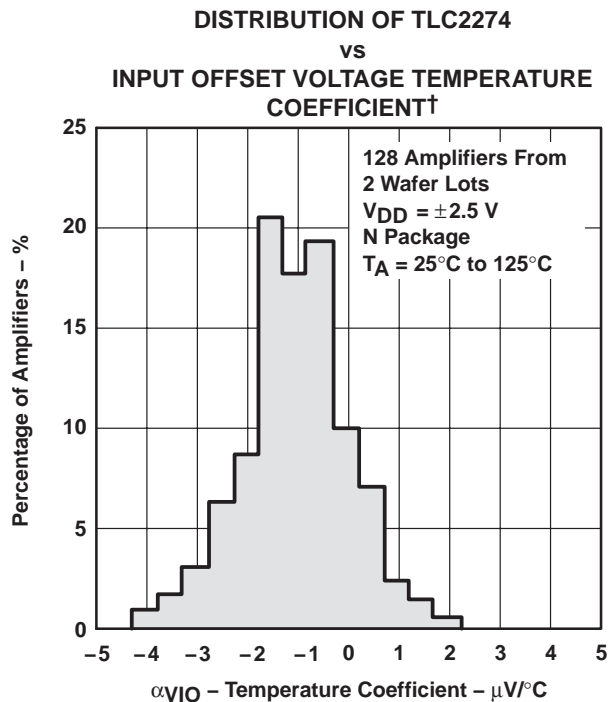


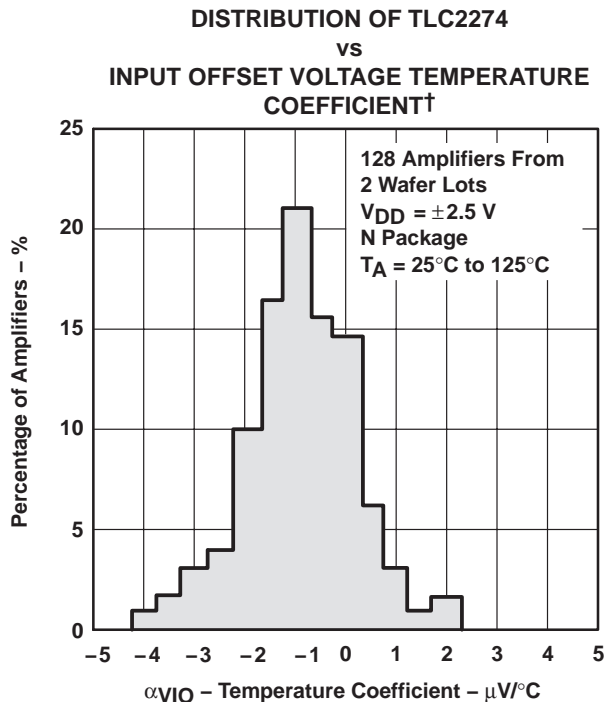
Figure 8

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

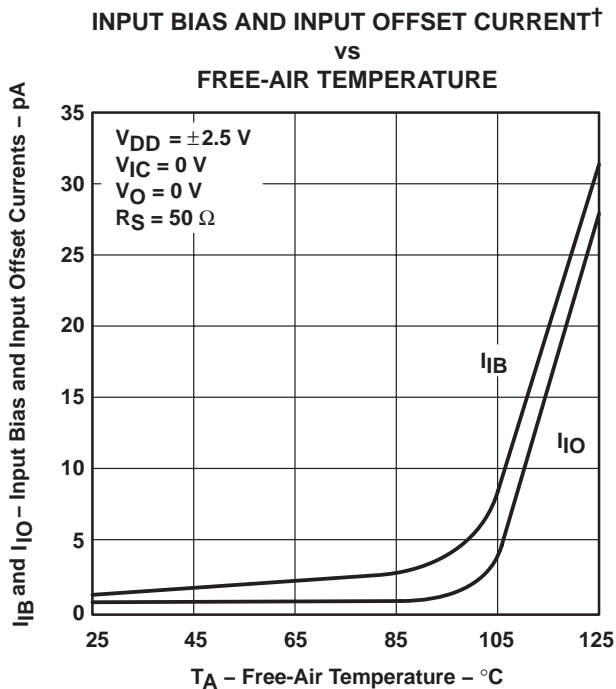
**TYPICAL CHARACTERISTICS**



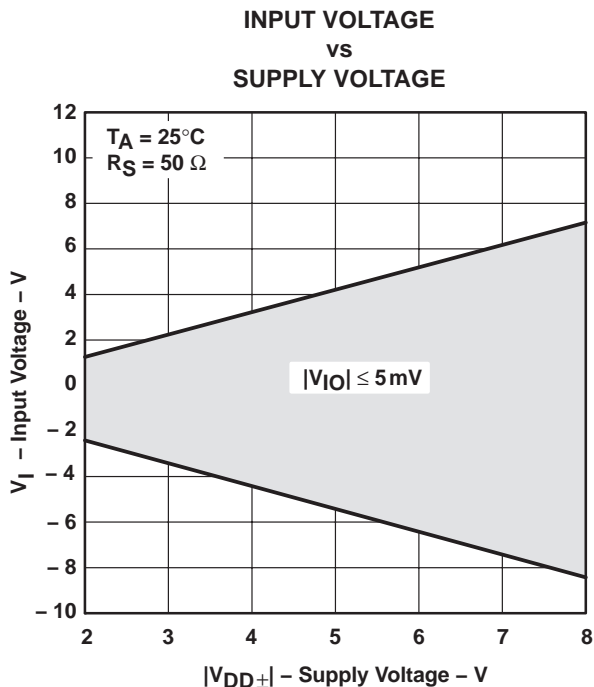
**Figure 9**



**Figure 10**



**Figure 11**



**Figure 12**

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS

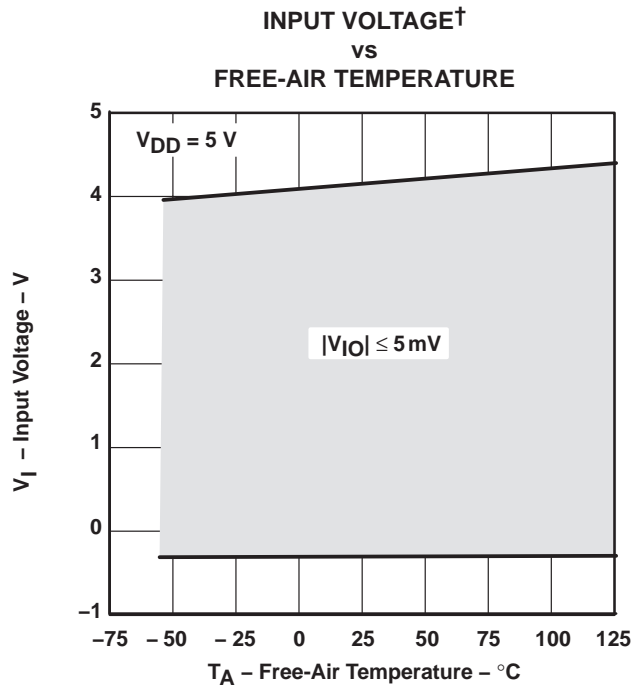


Figure 13

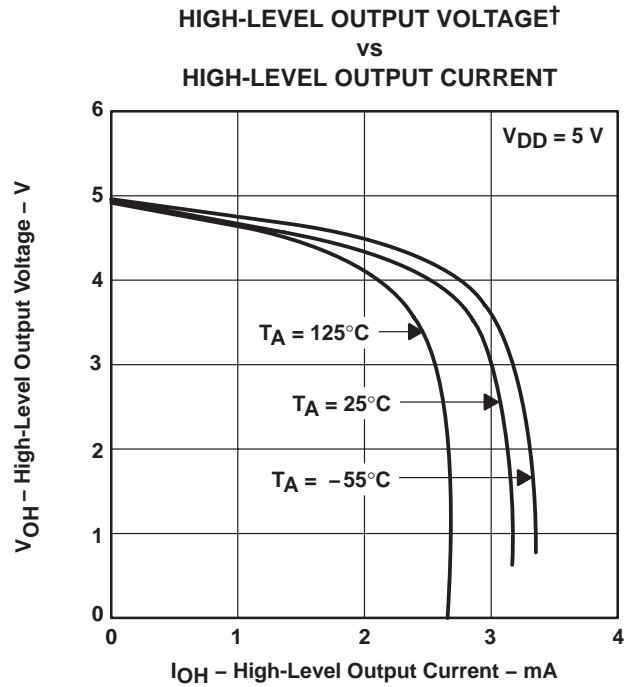


Figure 14

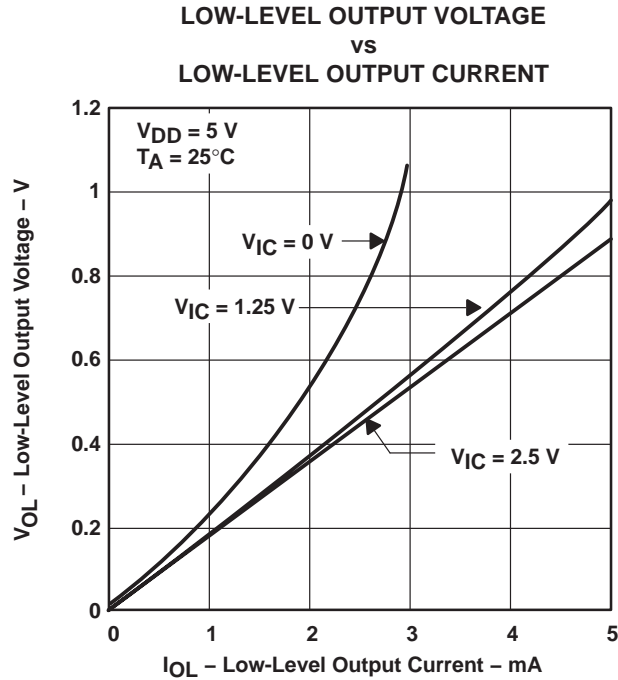


Figure 15

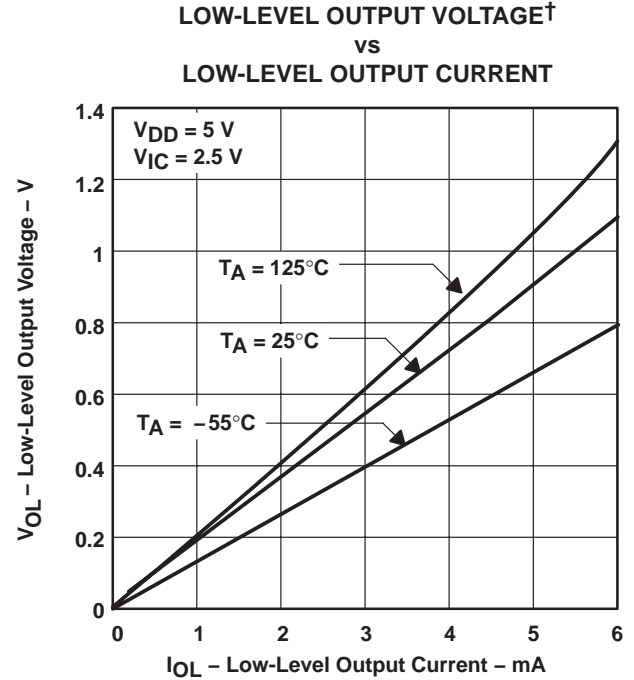
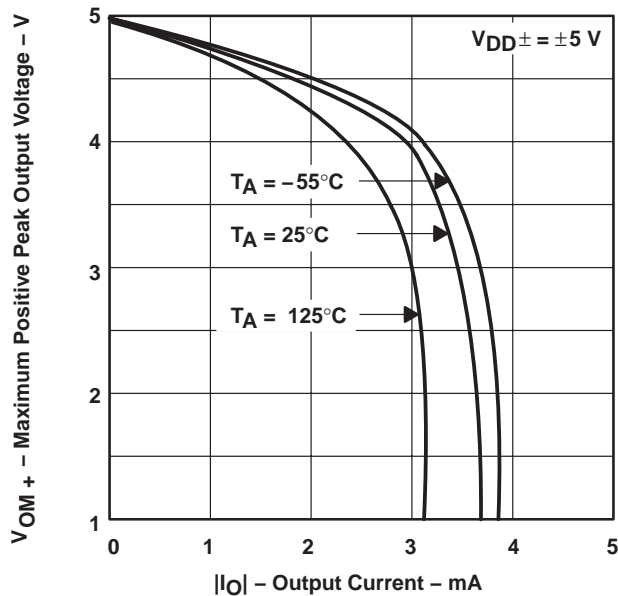


Figure 16

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

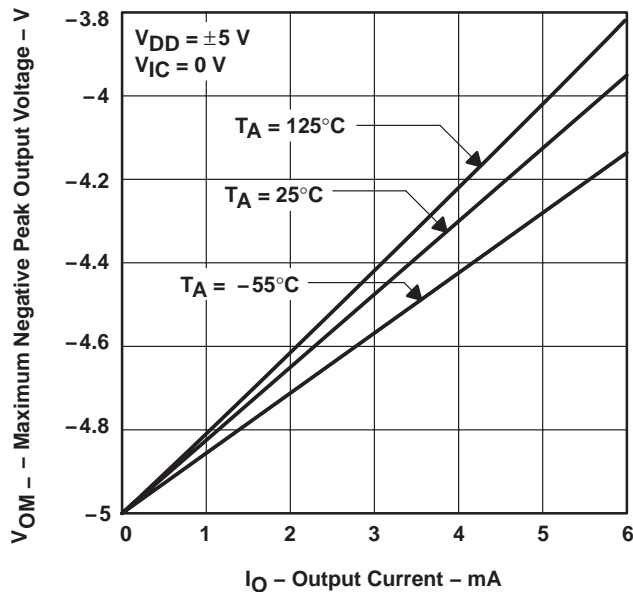
**TYPICAL CHARACTERISTICS**

**MAXIMUM POSITIVE PEAK OUTPUT VOLTAGE†**  
**vs**  
**OUTPUT CURRENT**



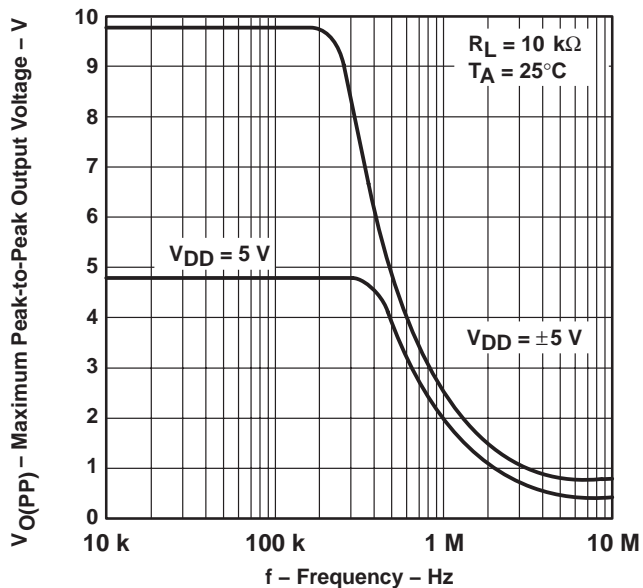
**Figure 17**

**MAXIMUM NEGATIVE PEAK OUTPUT VOLTAGE†**  
**vs**  
**OUTPUT CURRENT**



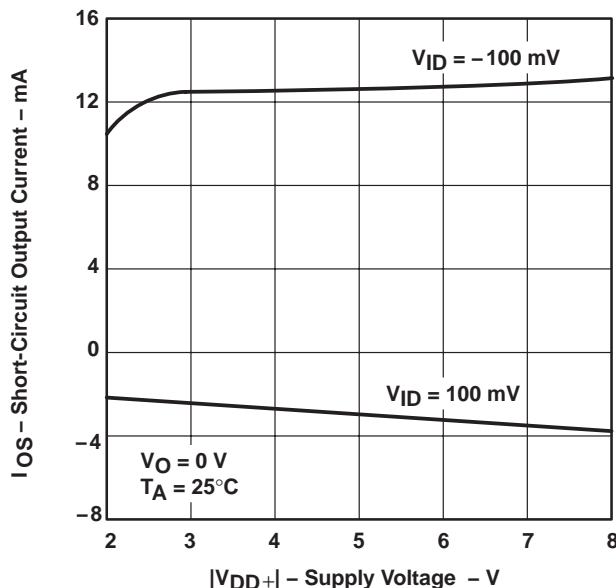
**Figure 18**

**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE**  
**vs**  
**FREQUENCY**



**Figure 19**

**SHORT-CIRCUIT OUTPUT CURRENT**  
**vs**  
**SUPPLY VOLTAGE**



**Figure 20**

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

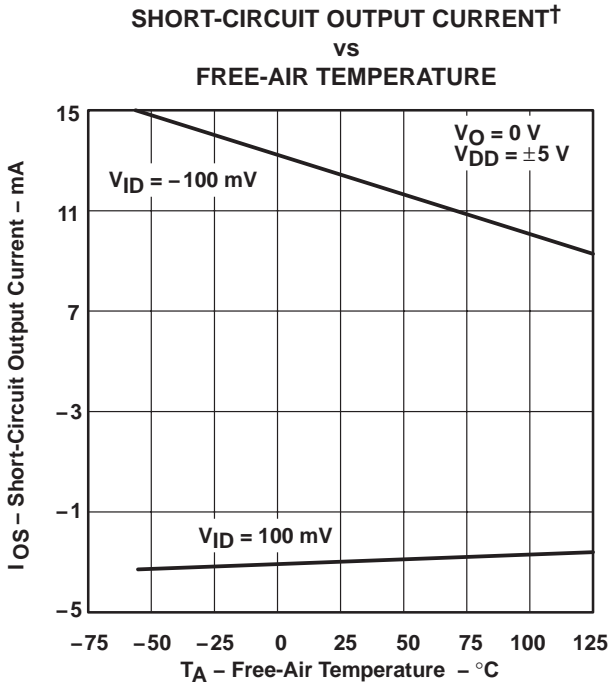


Figure 21

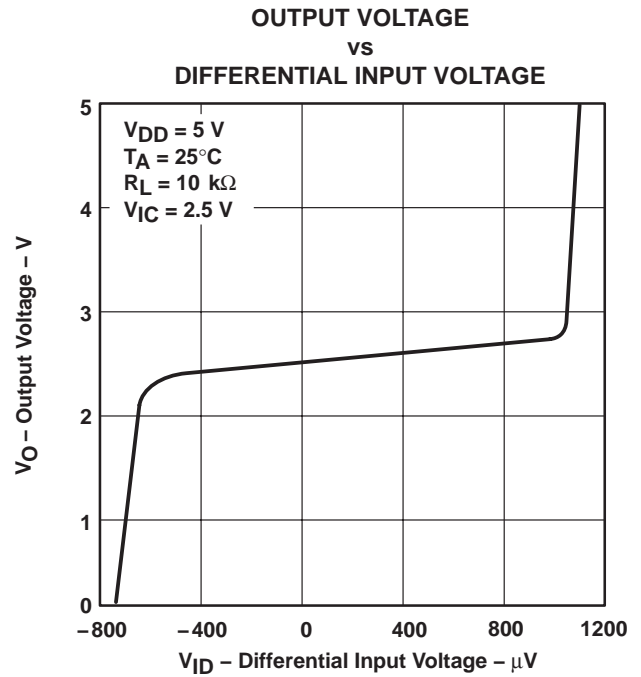


Figure 22

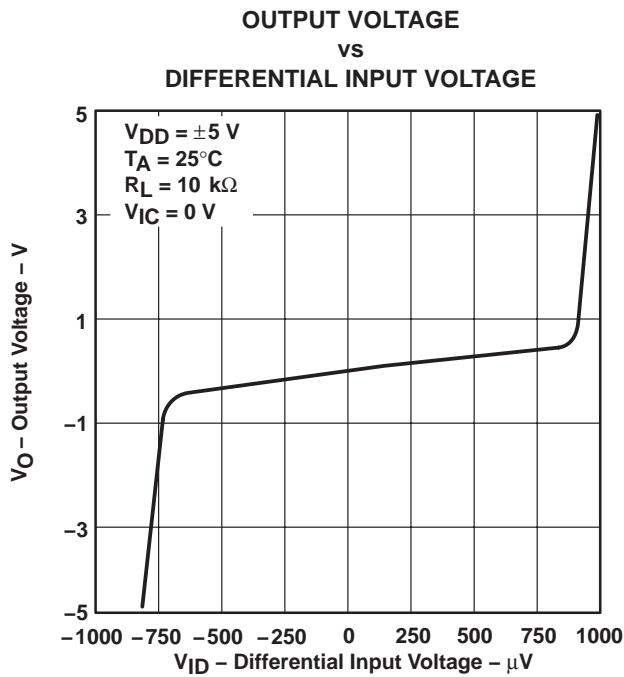


Figure 23

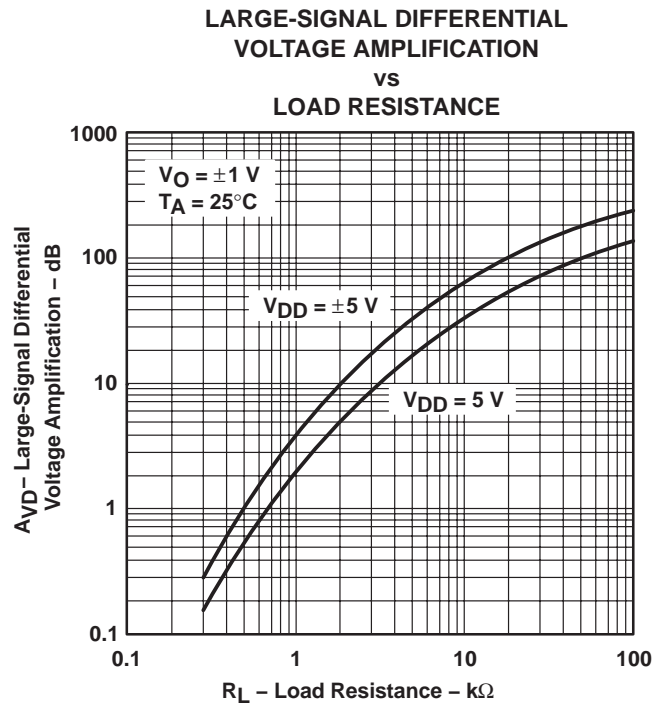


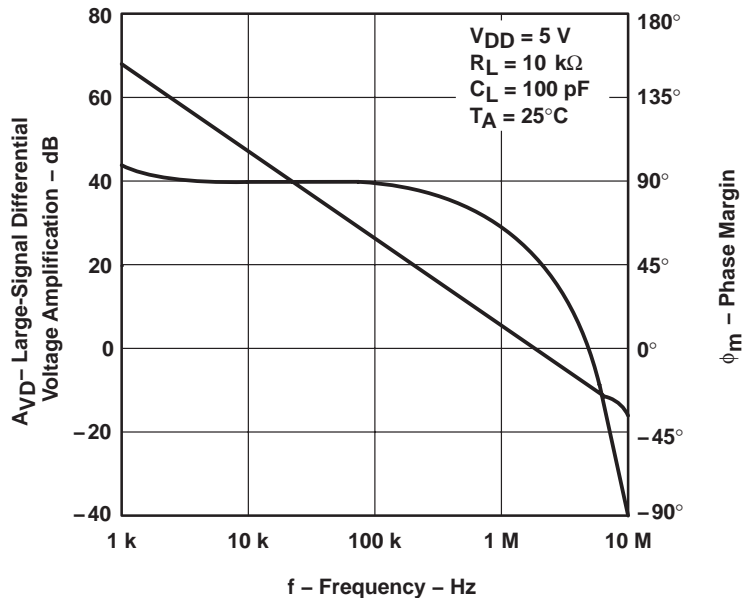
Figure 24

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

**TYPICAL CHARACTERISTICS**

**LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN**

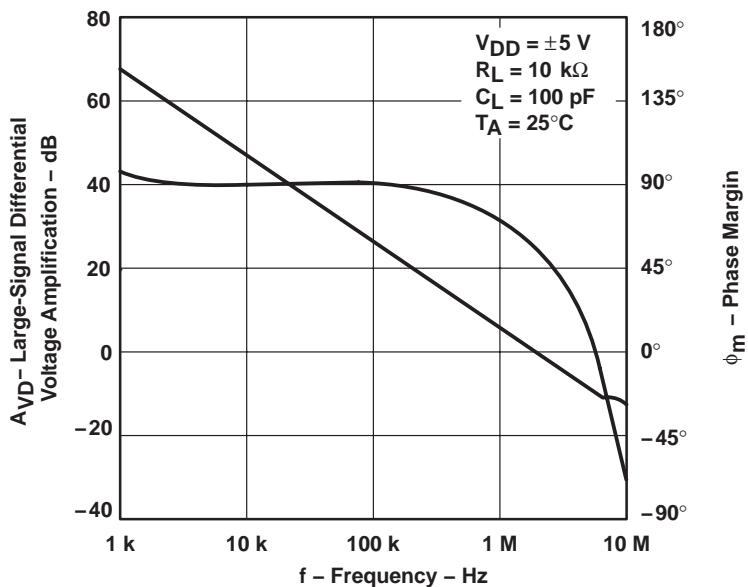
**vs**  
**FREQUENCY**



**Figure 25**

**LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN**

**vs**  
**FREQUENCY**



**Figure 26**

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL  
 VOLTAGE AMPLIFICATION†  
 vs  
 FREE-AIR TEMPERATURE

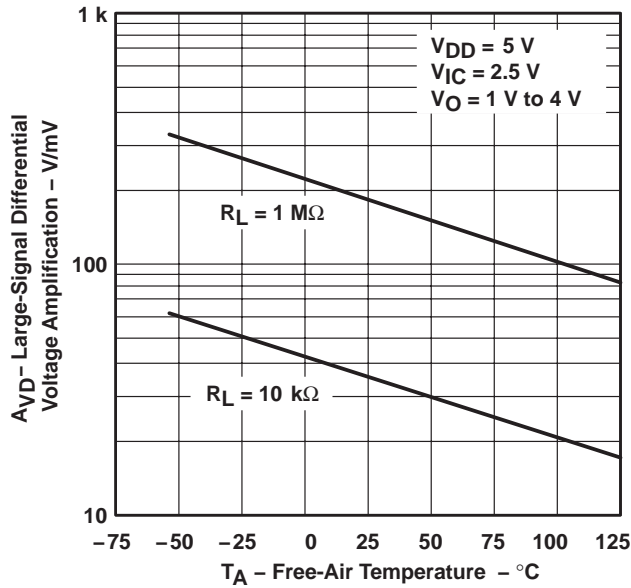


Figure 27

LARGE-SIGNAL DIFFERENTIAL  
 VOLTAGE AMPLIFICATION†  
 vs  
 FREE-AIR TEMPERATURE

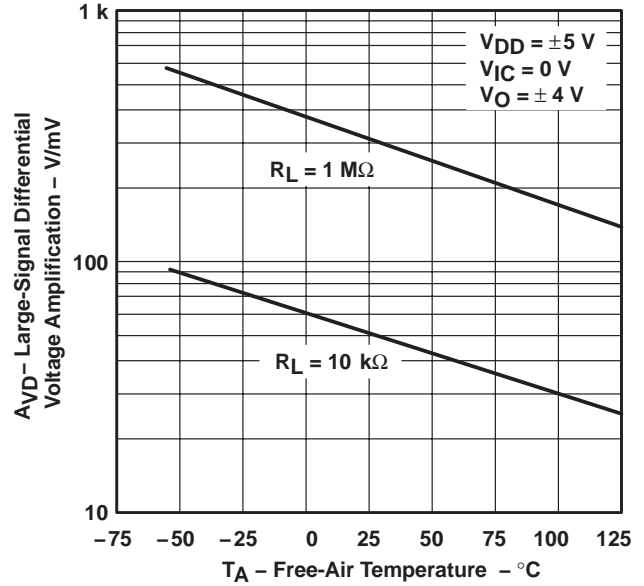


Figure 28

OUTPUT IMPEDANCE  
 vs  
 FREQUENCY

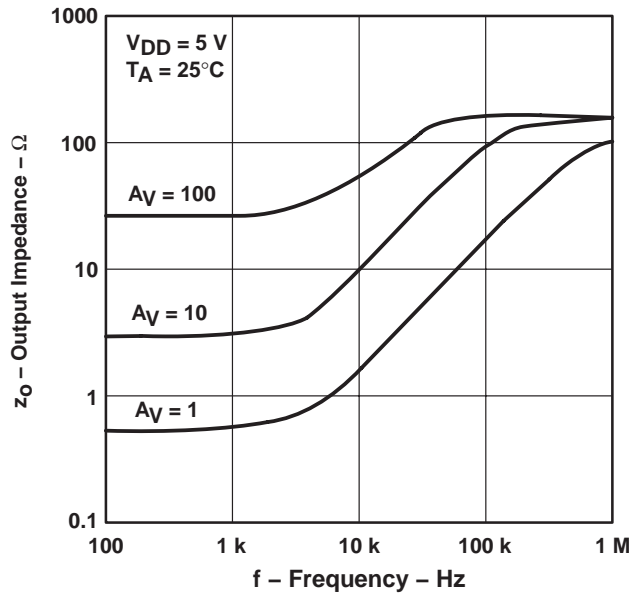


Figure 29

OUTPUT IMPEDANCE  
 vs  
 FREQUENCY

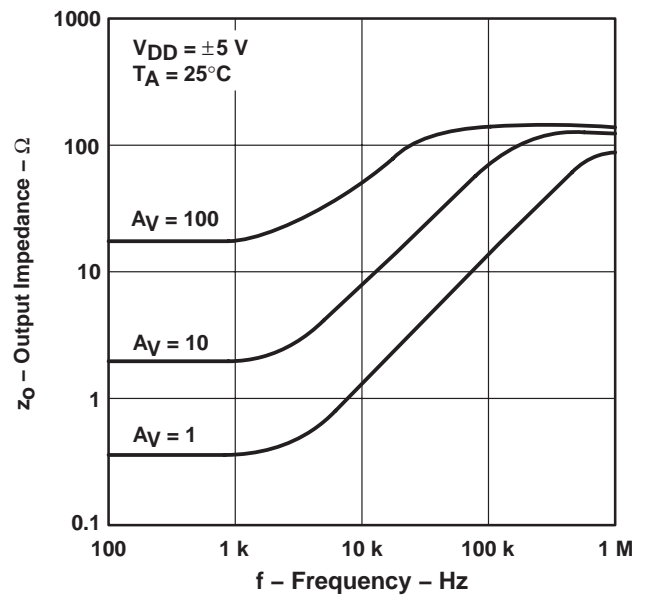
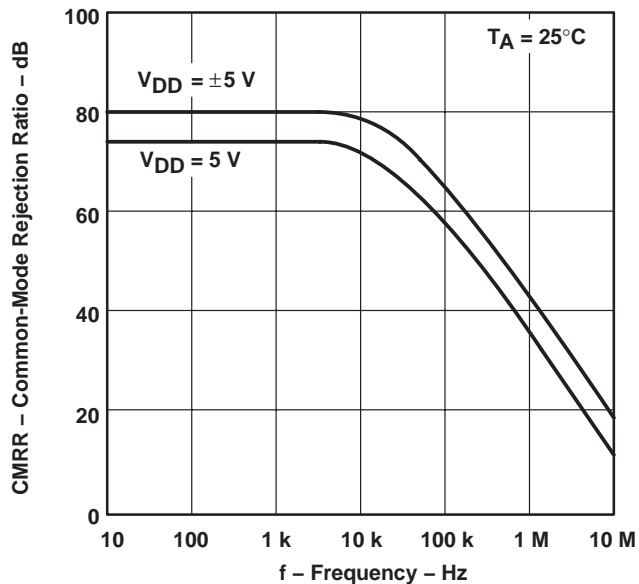


Figure 30

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

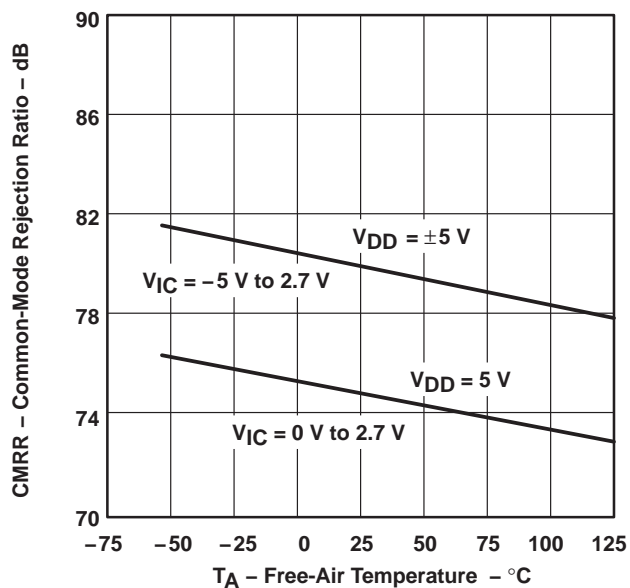
**TYPICAL CHARACTERISTICS**

**COMMON-MODE REJECTION RATIO  
 vs  
 FREQUENCY**



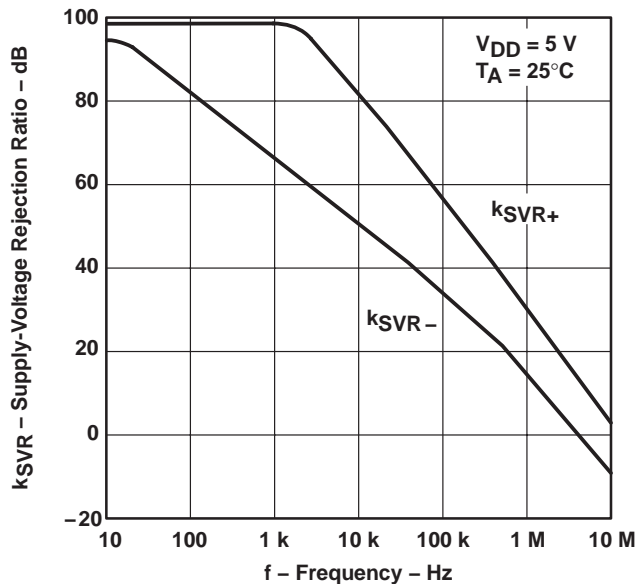
**Figure 31**

**COMMON-MODE REJECTION RATIO  
 vs  
 FREE-AIR TEMPERATURE**



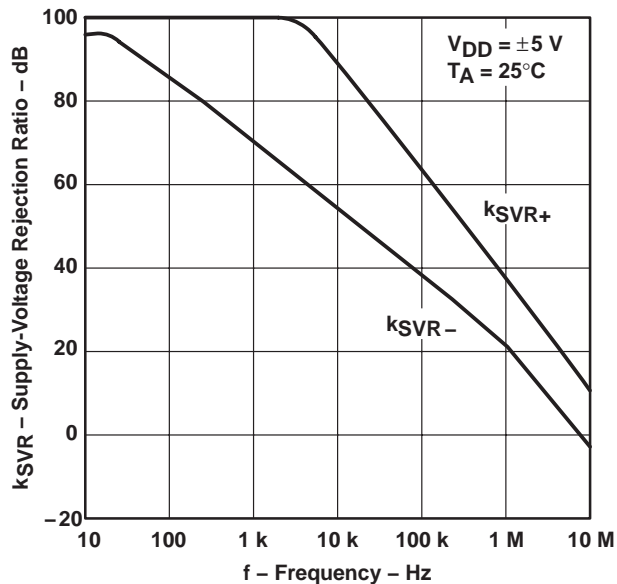
**Figure 32**

**SUPPLY-VOLTAGE REJECTION RATIO  
 vs  
 FREQUENCY**



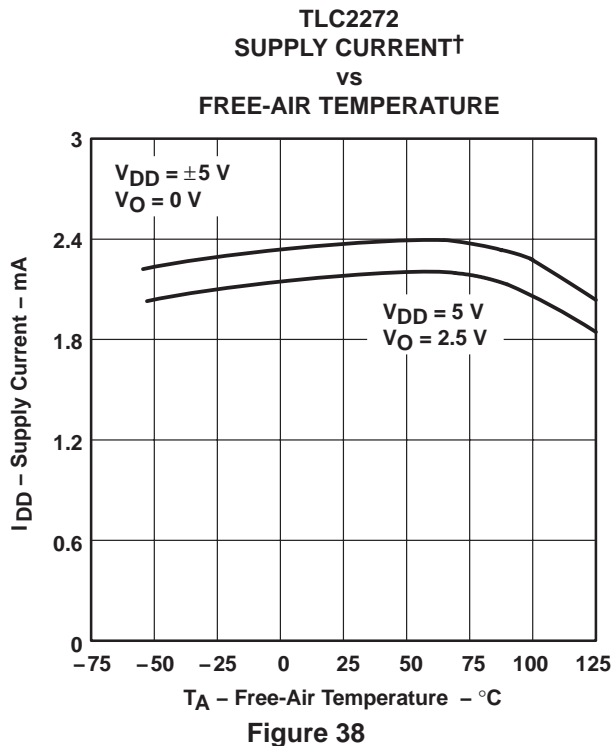
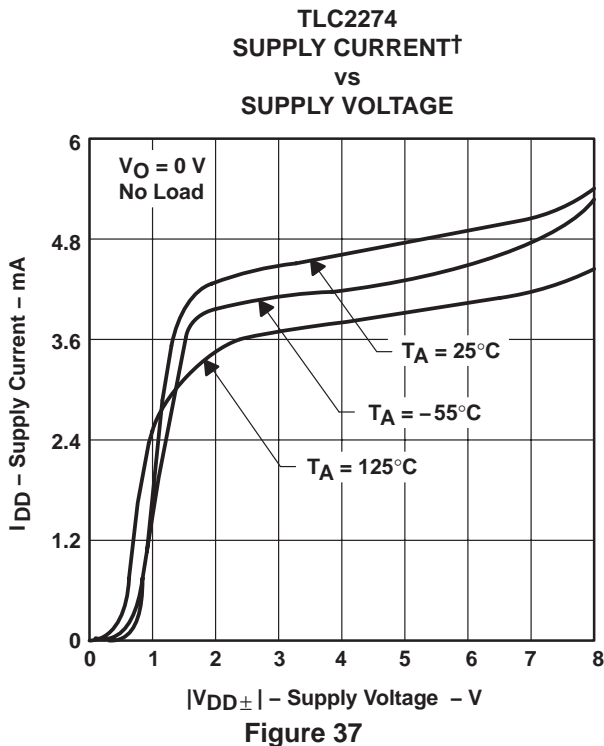
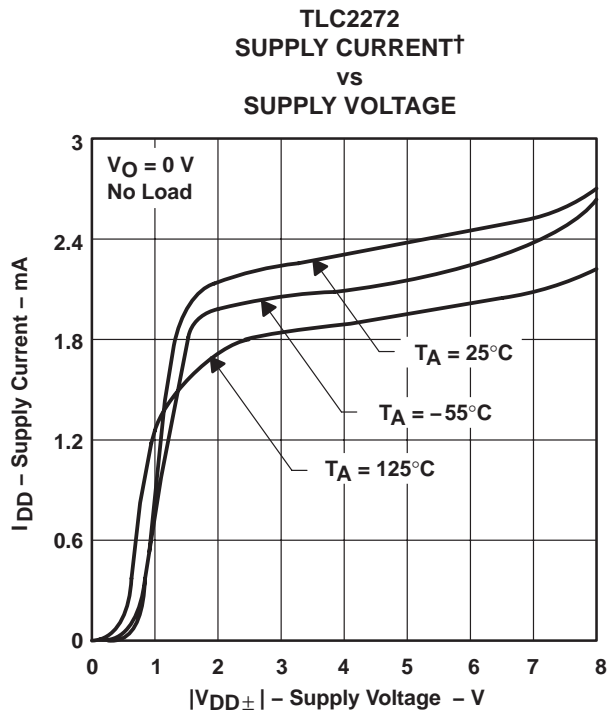
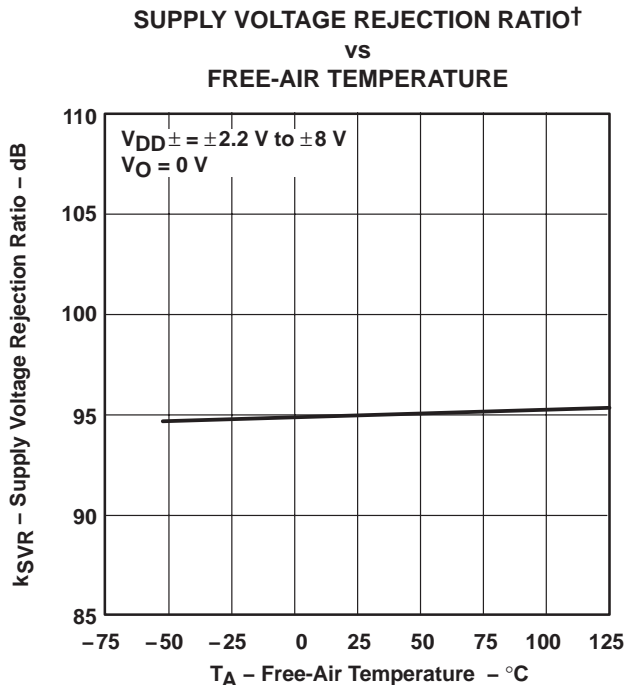
**Figure 33**

**SUPPLY-VOLTAGE REJECTION RATIO  
 vs  
 FREQUENCY**



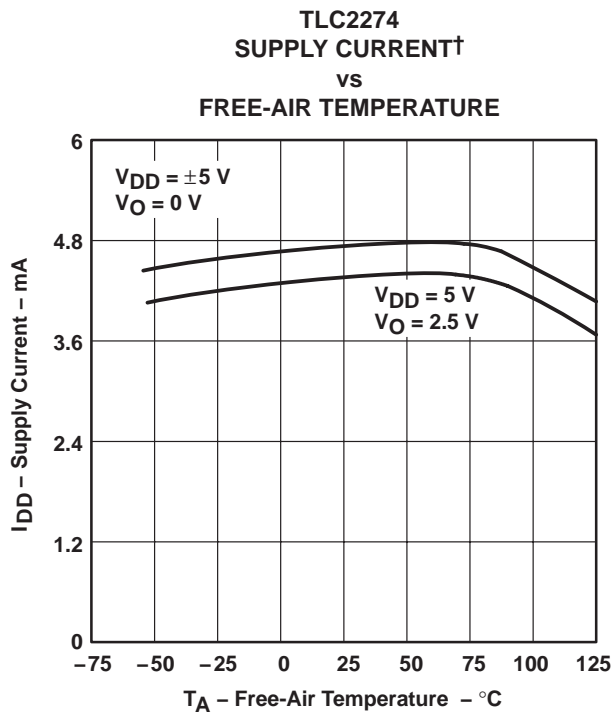
**Figure 34**

TYPICAL CHARACTERISTICS

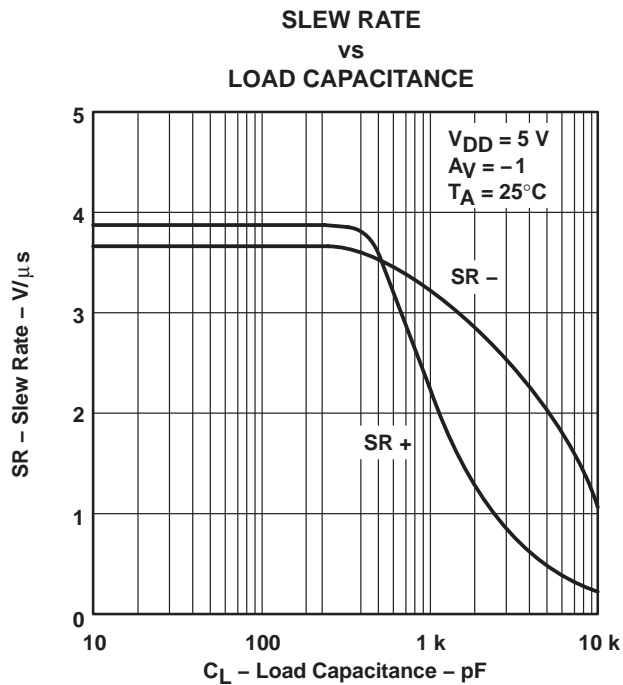


† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

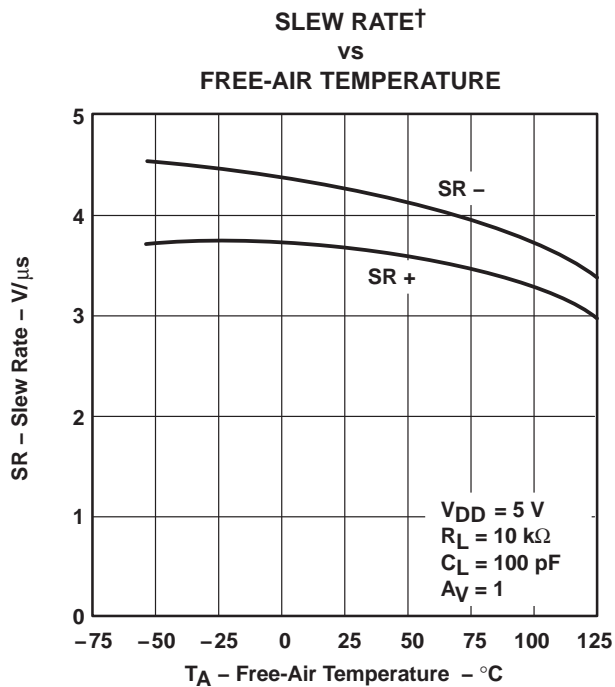
**TYPICAL CHARACTERISTICS**



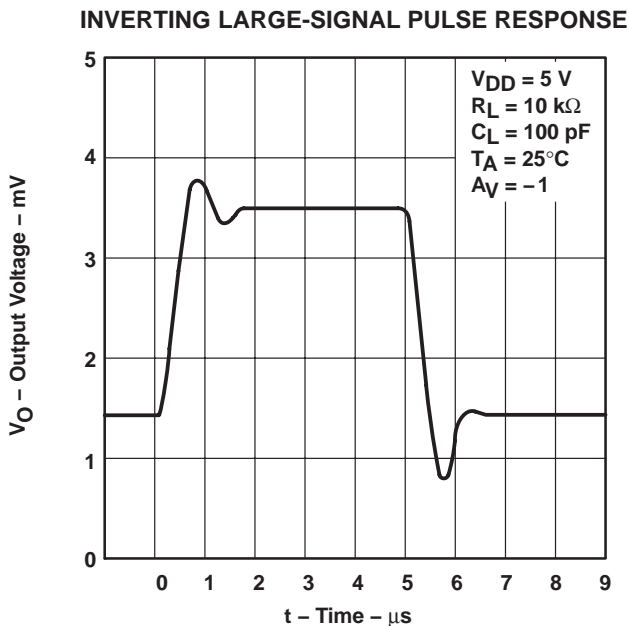
**Figure 39**



**Figure 40**



**Figure 41**



**Figure 42**

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS

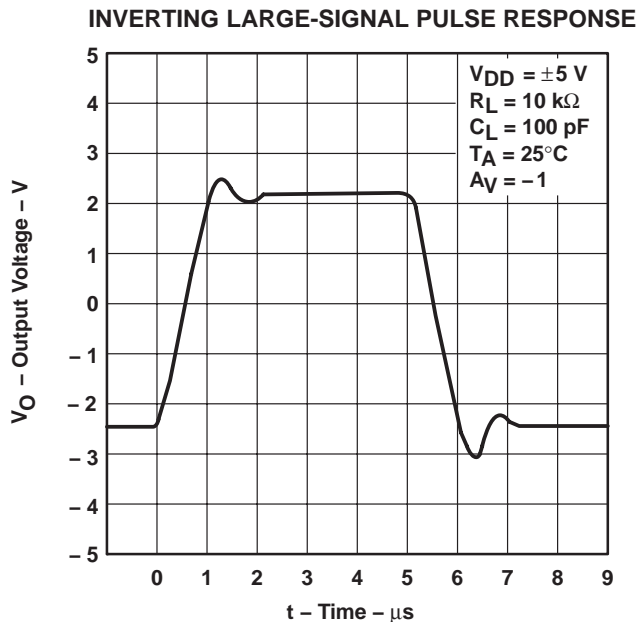


Figure 43

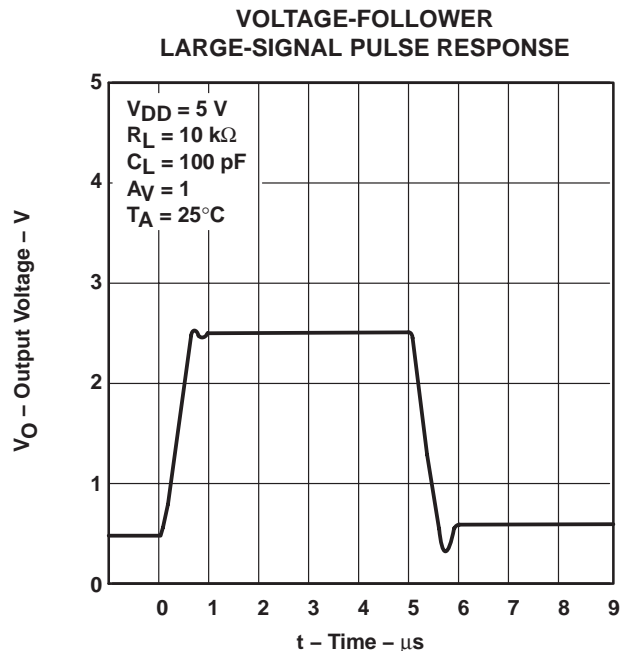


Figure 44

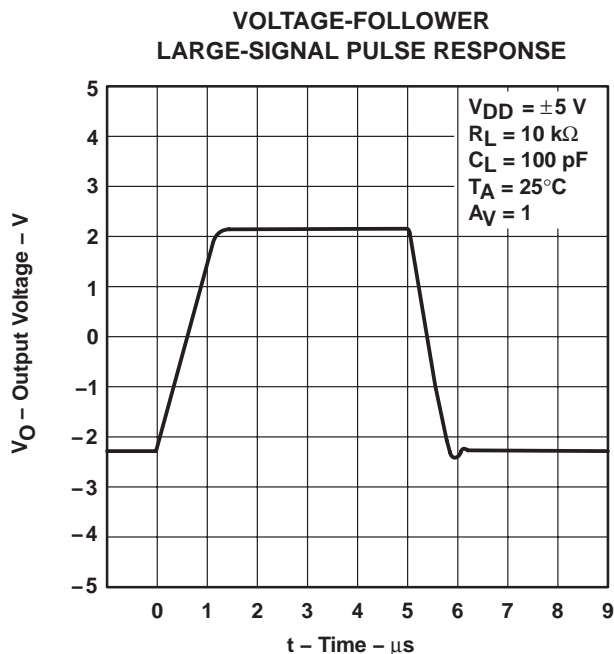


Figure 45

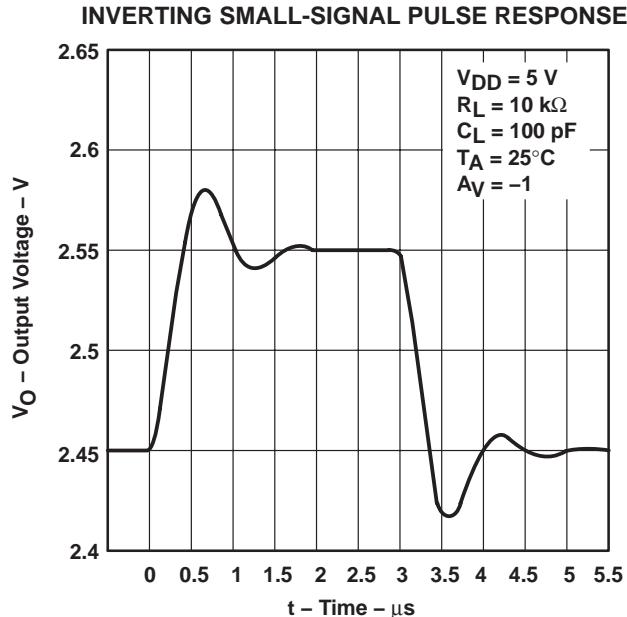
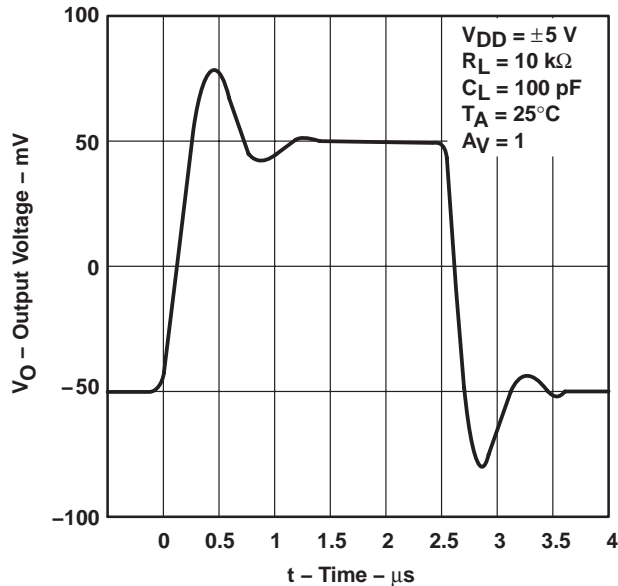


Figure 46

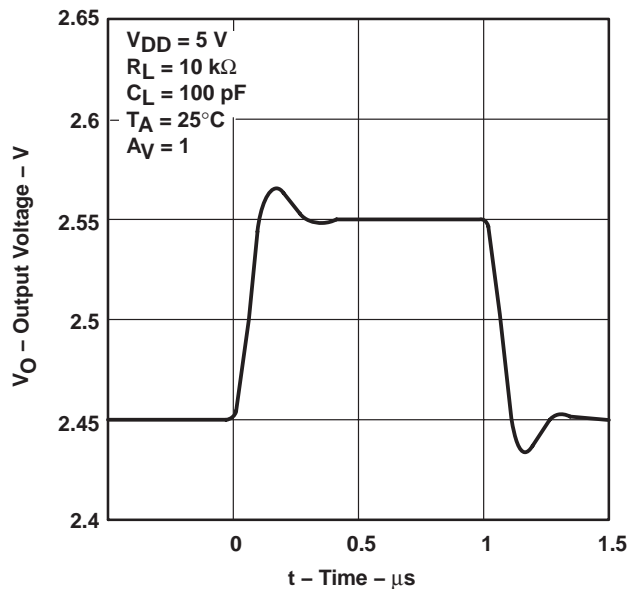
**TYPICAL CHARACTERISTICS**

**INVERTING SMALL-SIGNAL PULSE RESPONSE**



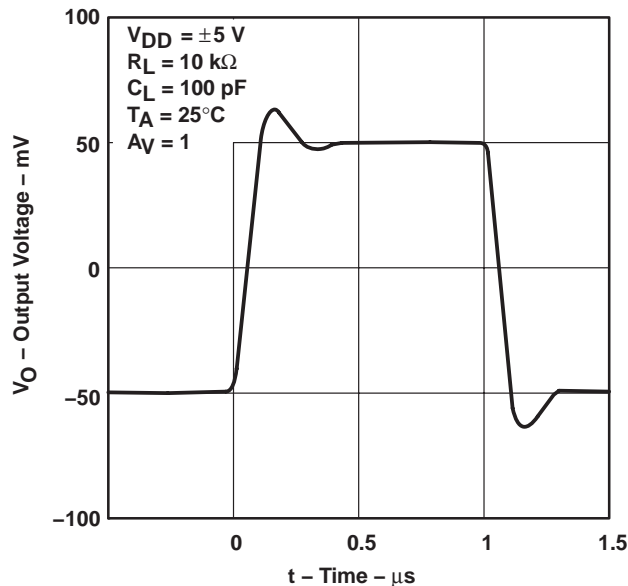
**Figure 47**

**VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE**



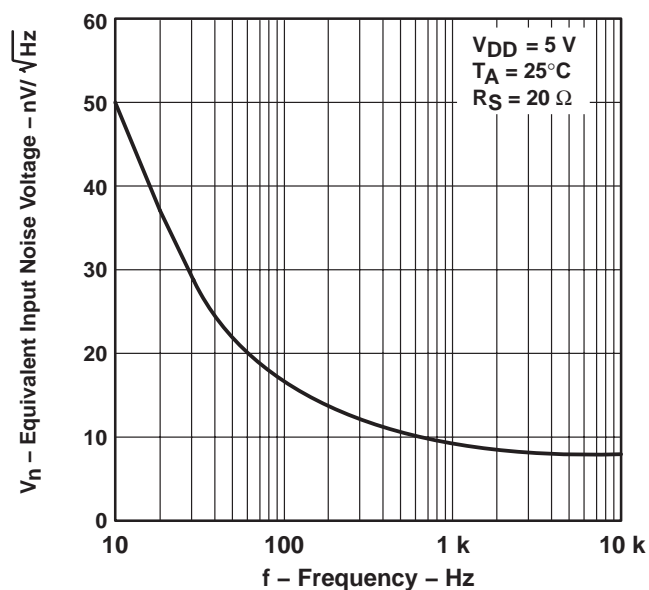
**Figure 48**

**VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE**



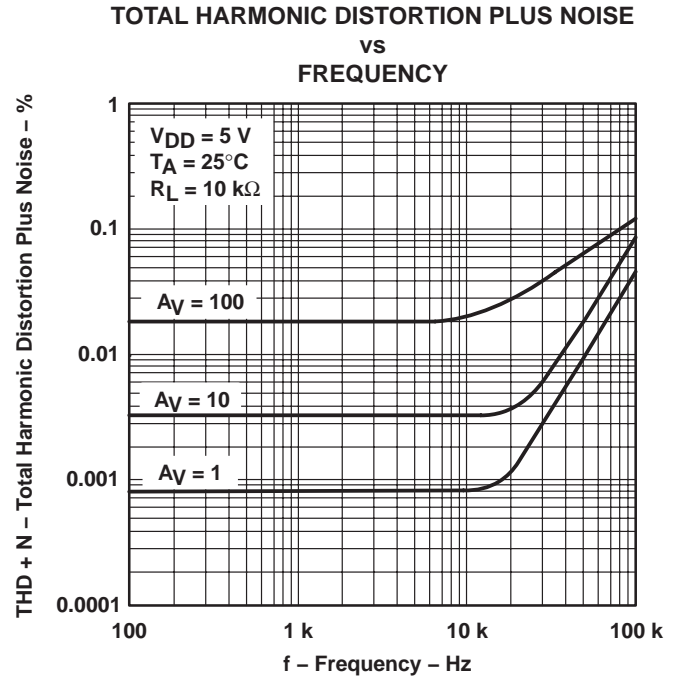
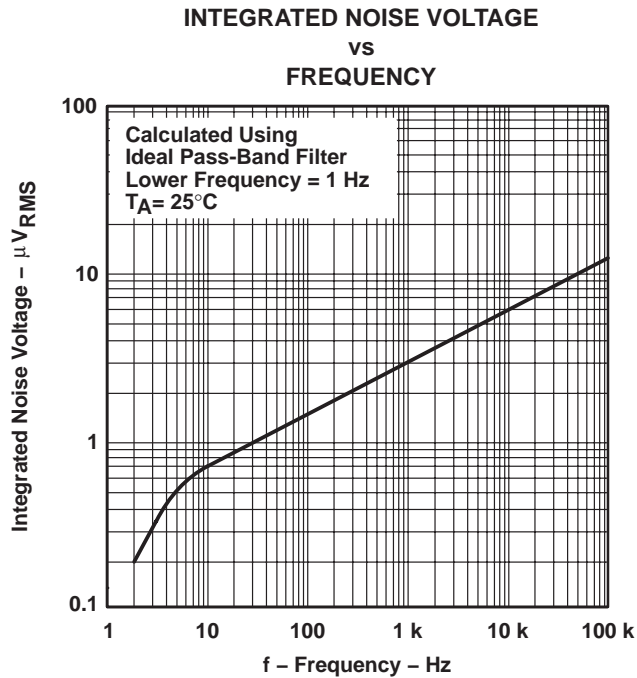
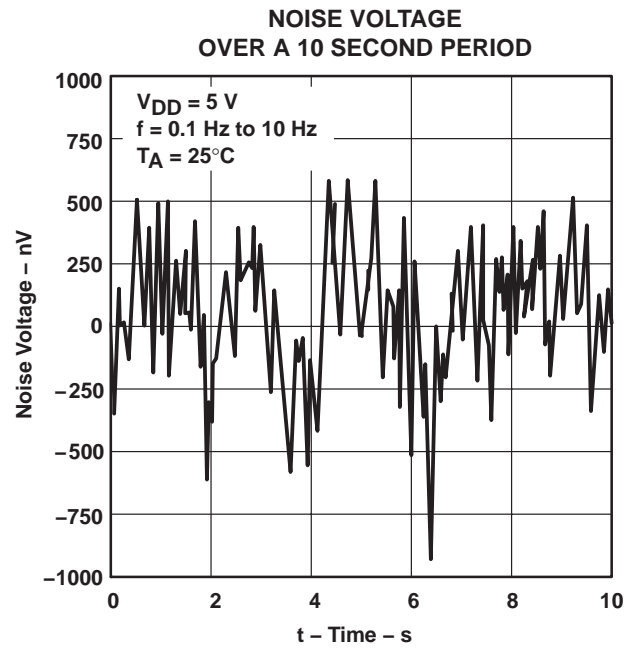
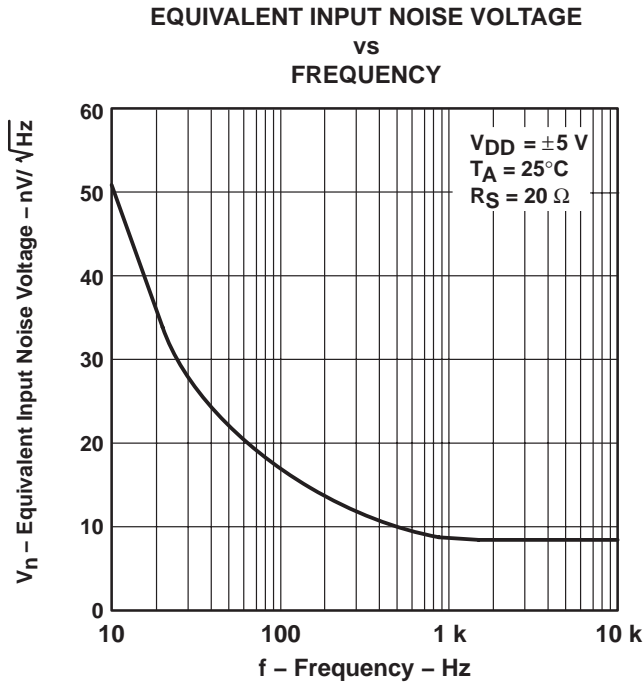
**Figure 49**

**EQUIVALENT INPUT NOISE VOLTAGE vs FREQUENCY**



**Figure 50**

TYPICAL CHARACTERISTICS

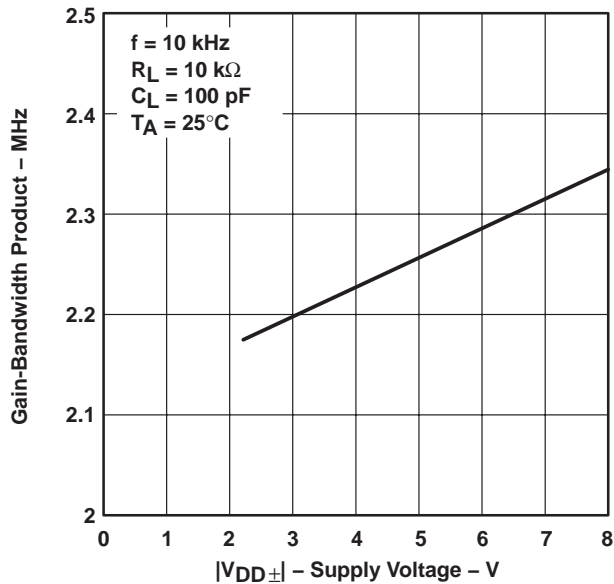


**TLC227x-Q1, TLC227xA-Q1**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SGLS007C – FEBRUARY 2003 – REVISED APRIL 2008

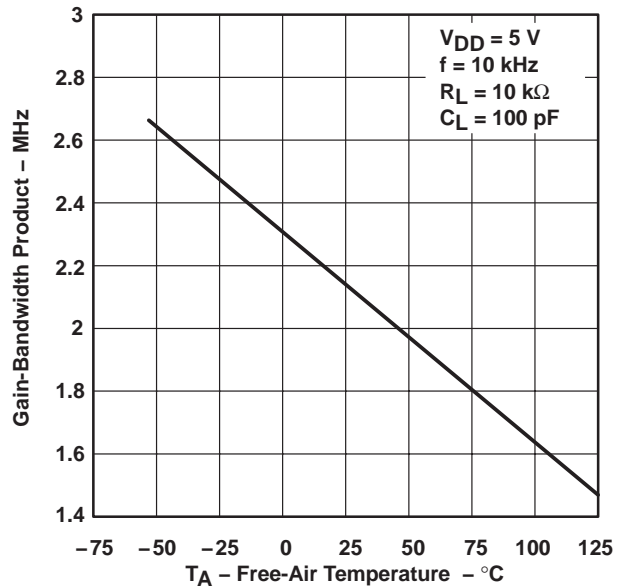
**TYPICAL CHARACTERISTICS**

**GAIN-BANDWIDTH PRODUCT**  
**vs**  
**SUPPLY VOLTAGE**



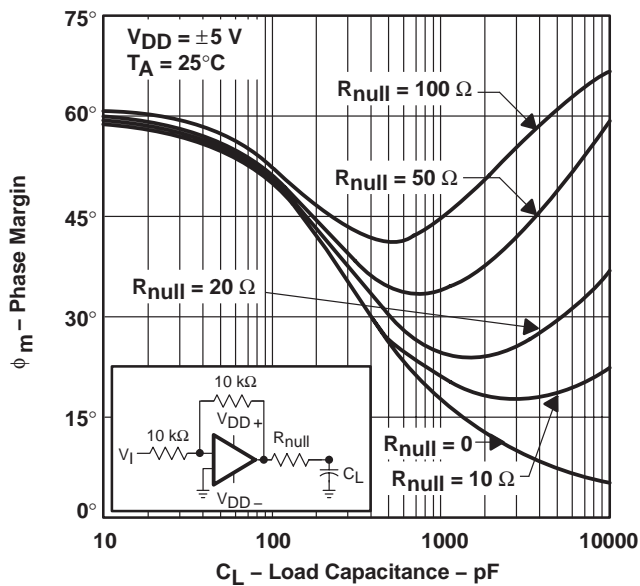
**Figure 55**

**GAIN-BANDWIDTH PRODUCT†**  
**vs**  
**FREE-AIR TEMPERATURE**



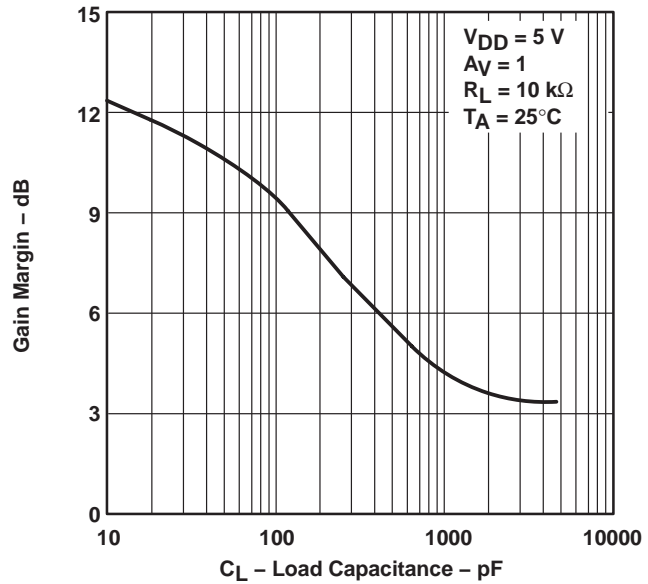
**Figure 56**

**PHASE MARGIN**  
**vs**  
**LOAD CAPACITANCE**



**Figure 57**

**GAIN MARGIN**  
**vs**  
**LOAD CAPACITANCE**



**Figure 58**

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim *Parts*™, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 5) and subcircuit in Figure 59 were generated using the TLC227x typical electrical and operating characteristics at T<sub>A</sub> = 25°C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 5: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

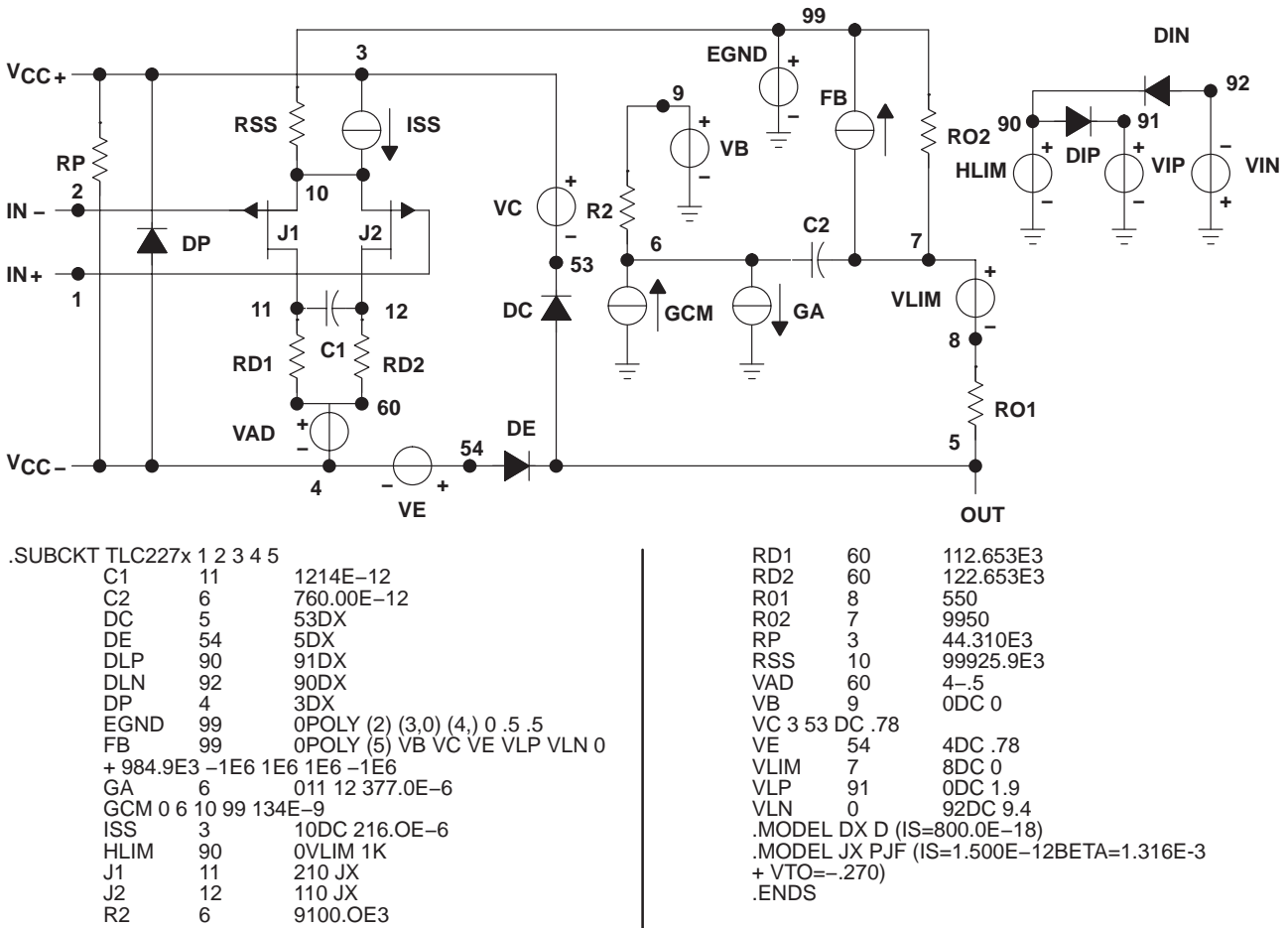


Figure 59. Boyle Macromodel and Subcircuit

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Macromodels, simulation models, or other models provided by TI, directly or indirectly, are not warranted by TI as fully representing all of the specification and operating characteristics of the semiconductor product to which the model relates.



**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TLC2272AQDRG4Q1	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC2272AQDRQ1	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
TLC2272AQPWRG4Q1	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC2272AQPWRQ1	ACTIVE	TSSOP	PW	8	2000	TBD	CU NIPDAU	Level-1-250C-UNLIM
TLC2272QDRG4Q1	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC2272QDRQ1	ACTIVE	SOIC	D	8	2500	TBD	CU NIPDAU	Level-1-220C-UNLIM
TLC2272QPWRG4Q1	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC2272QPWRQ1	ACTIVE	TSSOP	PW	8	2000	TBD	CU NIPDAU	Level-1-250C-UNLIM
TLC2274AQDRG4Q1	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC2274AQDRQ1	ACTIVE	SOIC	D	14	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
TLC2274AQPWRG4Q1	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC2274AQPWRQ1	ACTIVE	TSSOP	PW	14	2000	TBD	CU NIPDAU	Level-1-250C-UNLIM
TLC2274QDRG4Q1	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC2274QDRQ1	ACTIVE	SOIC	D	14	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
TLC2274QPWRG4Q1	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC2274QPWRQ1	ACTIVE	TSSOP	PW	14	2000	TBD	CU NIPDAU	Level-1-250C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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**OTHER QUALIFIED VERSIONS OF TLC2272-Q1, TLC2272A-Q1, TLC2274-Q1, TLC2274A-Q1 :**

- Catalog: [TLC2272](#), [TLC2272A](#), [TLC2274](#), [TLC2274A](#)
- Enhanced Product: [TLC2272A-EP](#), [TLC2274-EP](#), [TLC2274A-EP](#)
- Military: [TLC2272M](#), [TLC2272AM](#), [TLC2274M](#), [TLC2274AM](#)

**NOTE: Qualified Version Definitions:**

- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications
- Military - QML certified for Military and Defense Applications

PW (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



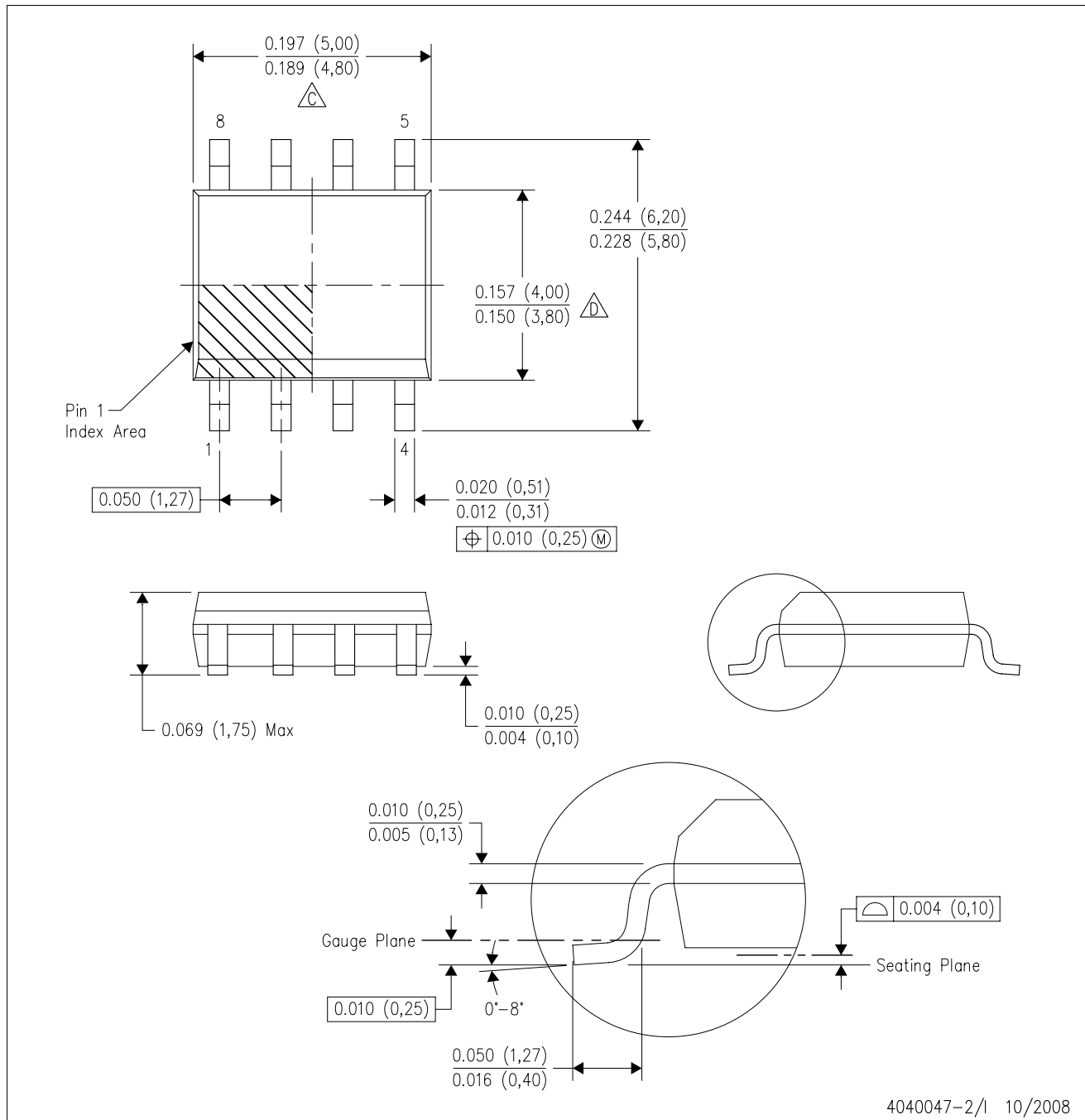
4040064/F 01/97

- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-153



D (R-PDSO-G8)

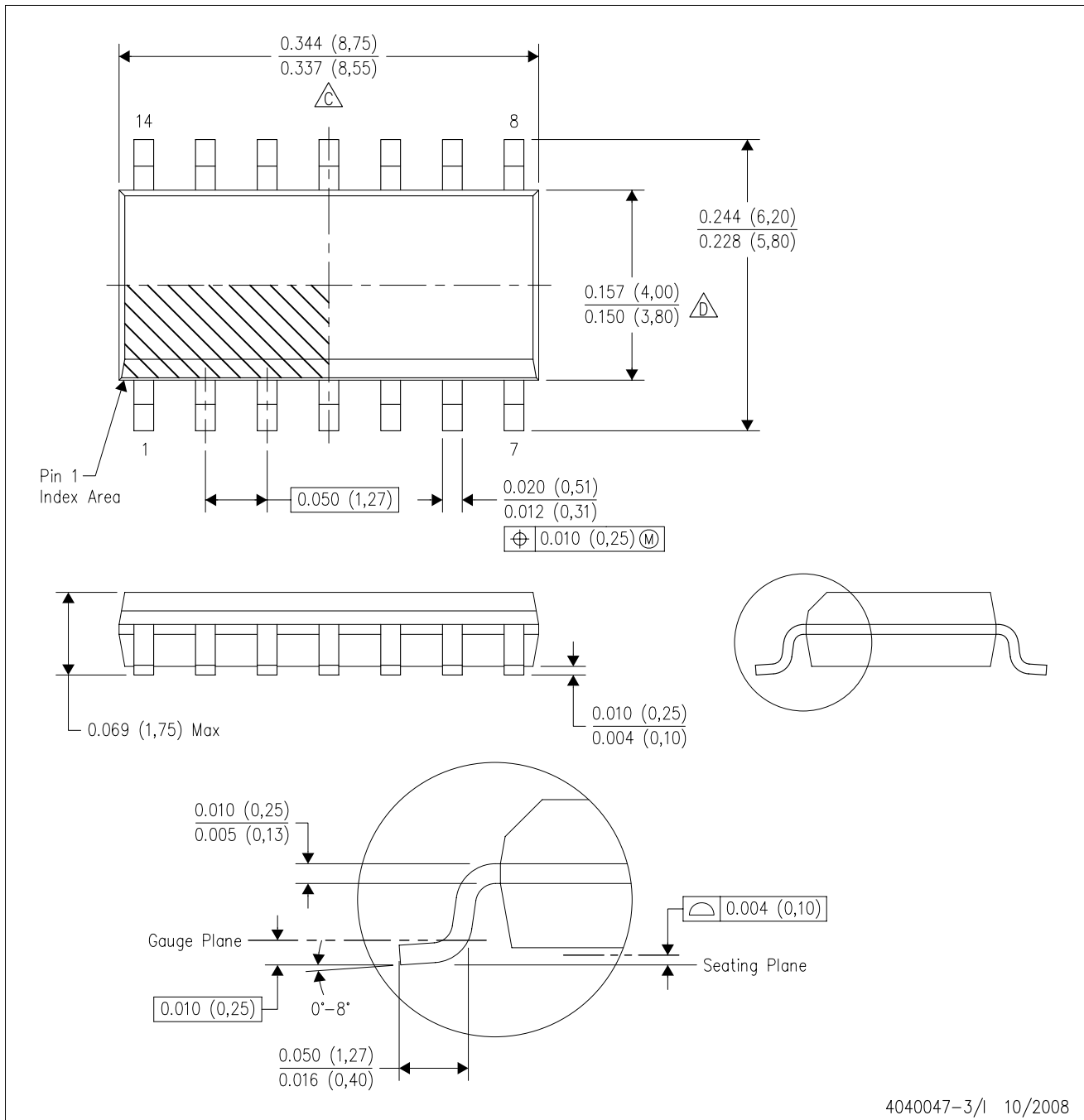
PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - $\Delta C$  Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
  - $\Delta D$  Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
  - E. Reference JEDEC MS-012 variation AA.

D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
  - E. Reference JEDEC MS-012 variation AB.

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